

	TABLE OF CONTENTS
1.	SPECIFICATIONS
2.	DISASSEMBLY INSTRUCTIONS
3.	BLOCK DIAGRAM 7
4.	CIRCUIT DESCRIPTION 8~9
	FREQUENCY CHART 10
5.	ABBREVIATED CIRCUIT DESCRIPTION OF RECEIVER 11
6.	ABBREVIATED DESCRIPTION OF TRANSMITTER
	CIRCUIT
7.	ALIGNMENT INSTRUCTIONS
8.	SEMICONDUCTOR VOLTAGE CHART
9.	TROUBLESHOOTING HINTS
10.	SEMICONDUCTOR PIN CONNECTIONS
11.	IC INTERNAL DIAGRAMS
12.	MAIN P.C. BOARD (TOP VIEW)23
13.	MAIN P.C. BOARD (BOTTOM VIEW)24
14.	ADDITIONAL PARTS ON THE P.C. BOARD BOTTOM 25
15.	OTHER P.C. BOARDS26
16.	WIRING DIAGRAM27
17.	ELECTRICAL PARTS LIST $\dots \dots 28 \sim 40$
18.	MECHANICAL PARTS LIST41
	SCHEMATIC DIAGRAM/EXPLODED
	VIEWSEPARATE SHEET

## 1. SPECIFICATIONS

### **GENERAL**:

Channels	: 40 Channels for AM, Upper Side Band and Lower Side Band, utilizing Digital Circuitry
Frequency Range	: 26.965 MHz to 27.405 MHz
Frequency Control	: Digital (Phase Lock Loop) Synthesizer
Frequency Accuracy	: ±100 Hz
Operating Temperature Range	: -20°C to +50°C
Power Requirements	: 13.8V DC (12-16 volts DC, negative or positive ground)
Antenna	: 52 ohm (Coaxial connector)
Microphone	: 600 ohm Dynamic Type
Speaker	: 16 ohm, 3 Watt
Size (H x W x D)	: 7-1/3''(W) x 2-1/3''(H) x 8-9/10(D)
Weight	: 10 lbs. (4.5 kg)
Accessories	: DC Cord with in-line Fuse, Microphone and Microphone Bracket and Mounting Bracket

### **MEASUREMENT CONDITION:**

Power Source	: 13.8V DC
Antenna Impedance	: 50 ohm
Test Temperature	: 25°C
AM Modulation Frequency	: 1 kHz
SSB Modulation Frequency, Transmit	: Two tone: 500 Hz and 2400 Hz Single tone: 1 kHz
Mean Signal Input Level	: 1000 μV
Reference Audio Output Power	: 0.5 W
Reference AM Modulation Percentage	: 1 kHz, 30%
Audio Frequency, SSB Receive	: 1 kHz
Audio Output Load	: 8 ohms resistive
Measuring Channel	: 19

- 3 -

Max. Sensitivity         : AM $\mu$ V         0.5         1           Max. Sensitivity         for 10 dB S/N         : AM $\mu$ V         0.25         0.5           Sensitivity for 10 dB S/N         : AM $\mu$ V         0.25         0.5           AGC Figure-of-Merit 100 mV for         : SSB         #V         0.25         0.5           AGC Figure-of-Merit 100 mV for         : AM         dB         90         80           Overload AGC Characteristics from         : SSB         dB         ±3         ±5           Overall Audio Fidelity at -6 dB Down         : AM         Hz         3500         2500 ~ 2500           Lower Frequency         : AM         HZ         3500         2600 ~ 650           Lower Frequency         : AM         HZ         450         250 ~ 650           Cross Modulation, RS Standard         : AM         dB         70         60           Adjacent Channel Selectivity (10 kHz)         : AM         W         4         3           SSB         W         4         3         2.5           SSB         W         3         6         6           Adjacent Channel Selectivity (10 kHz)         : AM         W         3         2.5	RECEIVER: (ANL & Noise Blanker Switch OFF)				· · · · · · · · · · · · · · · · · · ·
SSB $\mu$ V         0.25         0.5           Sensitivity for 10 dB S/N         AM $\mu$ V         0.25         1           SSB $\mu$ V         0.25         0.5         1           AGC Figure-of-Merit 100 mV for         SSB         dB         90         80           Overload AGC Characteristics from         SSB         dB         90         80           Overall Audio Fidelity at -6 dB Down          1750 ~ 2500         2500 ~ 5000           Lower Frequency         AM         Hz         450         250 ~ 650           Lower Frequency         AM         Hz         450         250 ~ 650           Cross Modulation, RS Standard         AM         dB         70         60           Adjacent Channel Selectivity (10 kHz)         AM         dB         70         60           Maximum Audio Output Power         AM         W         4         3           Audio Output Power at 10% THD         AM         %         3         2.5           THD at 500 mW Audio Output         AM         %         3         6           AM         M         %         3         6         3           SSB         BB         40			UNIT	NOMINAL	LIMIT
Sensitivity for 10 dB S/N       : AM $\mu V$ 0.5       1         AGC Figure of Merit 100 mV for       : AM       dB       90       80         10 dB Change in Audio Output       : AM       dB       90       80         Overload AGC Characteristics from       : AM       dB       ±3       ±5         Overlad AGC Characteristics from       : AM       dB       ±3       ±5         Overlad AGC Frequency       : AM       Hz       2100       1750 ~ 2500         Upper Frequency       : AM       Hz       450       250 ~ 650         Lower Frequency       : AM       Hz       450       250 ~ 650         Cross Modulation, RS Standard       : AM       dB       60       50         Adjacent Channel Selectivity (10 kHz)       : AM       W       4       3         SSB       dB       70       60       55       8         Audio Output Power at 10% THD       : AM       W       4       3       2.5         THD at 500 mW Audio Output       : AM       %       5       8       8         SSB:       1 mV Input, 30% modulation       : AM       %       5       8         SSB:       1 mV Input, 30% modulation <th>Max. Sensitivity</th> <th></th> <th>•</th> <th></th> <th></th>	Max. Sensitivity		•		
SSB $\mu V$ 0.25       0.5         AGC Figure-of-Merit 100 mV for       10 dB Change in Audio Output       :AM       dB       90       80         Overload AGC Characteristics from       :AM       dB       ±3       ±5         100 mV to 100 mV       :SSB       dB       ±3       ±5         Overall Audio Fidelity at -6 dB Down       :SSB       dB       ±3       ±5         Overall Audio Fidelity at -6 dB Down       :AM       Hz       2100       1750 ~ 2500         Lower Frequency       :AM       Hz       3500       2500 ~ 5000         Lower Frequency       :SSB       Hz       450       250 ~ 650         Cross Modulation, RS Standard       :AM       dB       60       50         Adjacent Channel Selectivity (10 kHz)       :AM       dB       70       60         Maximum Audio Output Power       :AM       W       4       3         Audio Output Power at 10% THD       :SSB       W       4       3         Audio Output Power at 10% THD       :AM       %       3       6         SSB       :ImV Input, 30% modulation       :AM       %       5       8         SSB       :B       :G       :SSB			-		0.5
AGC Figure-of-Merit 100 mV for 10 dB Change in Audio Output       SAB       dB       90       80         Overload AGC Characteristics from 100 mV to 100 mV       SAB       dB $\pm 3$ $\pm 5$ Overall Audio Fidelity at -6 dB Down Upper Frequency       IAM       Hz       2100       1750 ~ 2500         SSB       HZ       3500       2500 ~ 6500       SSB       HZ       3500       2500 ~ 6500         Lower Frequency       IAM       HZ       450       250 ~ 650       250 ~ 650         Cross Modulation, RS Standard       IAM       dB       60       50         Adjacent Channel Selectivity (10 kHz)       IAM       dB       70       60         Maximum Audio Output Power       IAM       W       3       2.5         THD at 500 mW Audio Output       IAM       W       3       2.5         THD at 500 mW Audio Output       IAM       %       3       6         SSB:       1 mV Input, 30% modulation       IAM       %       3       6         SSB:       1 mV Input, 1 kHz, Single-tone       ISSB       B       40       30 ~ 60         SSB:       1 mV Input       IAM       B       40       30 ~ 60       5       2	Sensitivity for 10 dB S/N				•
10 dB Change in Audio Output       : AM (B) (SB (B) (B) (SC) (SC) (SC) (SC) (SC) (SC) (SC) (SC		SSB	$\mu V$	0.25	0.5
SSB         dB         90         80           Overload AGC Characteristics from 100 mV to 100 mV         :AM         dB $\pm 3$ $\pm 5$ Overall Audio Fidelity at -6 dB Down Upper Frequency         :AM         Hz         2100         1750 ~ 2500           Lower Frequency         :AM         Hz         3500         2500 ~ 5000           Lower Frequency         :AM         Hz         450         250 ~ 650           Cross Modulation, RS Standard         :AM         dB         60         50           Adjacent Channel Selectivity (10 kHz)         :AM         dB         70         60           Adjacent Channel Selectivity (10 kHz)         :AM         W         4         3           Audio Output Power         :AM         W         4         3           Audio Output Power at 10% THD         :AM         W         3         2.5           THD at 500 mW Audio Output         :AM         %         3         6           SSB         :M         :M         %         3         6           SSB         :M         :SB         :SB         :SB         :SB           Audio Output Power at 10% THD         :AM         %         5         8					
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	10 dB Change in Audio Output				
100 mV to 100 mV       : AM       dB $\pm 3$ $\pm 5$ Overall Audio Fidelity at -6 dB Down		22B	ав	90	80
SSB         dB $\pm 3$ $\pm 5$ Overall Audio Fidelity at -6 dB Down Upper Frequency         : AM         Hz         2100         1750 ~ 2500           Lower Frequency         : AM         Hz         3500         2500 ~ 5000           Lower Frequency         : AM         Hz         450         250 ~ 650           Cross Modulation, RS Standard         : AM         dB         60         50           Adjacent Channel Selectivity (10 kHz)         : AM         dB         70         60           Maximum Audio Output Power         : AM         W         4         3           Audio Output Power at 10% THD         : AM         W         3         2.5           THD at 500 mW Audio Output         : AM         %         3         6           SSB         : 1 mV Input, 30% modulation         : AM         %         5         8           SSB         : 1 mV Input, 1 kHz, Single-tone         : SSB         %         3         6           SSB         : 1 mV Input, 1 kHz, Single-tone         : SSB         dB         40         30 ~ 60           SSB         : 1 mV Input         : AM         gB         40         34         5           SSB         : 1 mV				10	
Overall Audio Fidelity at -6 dB Down Upper Frequency         : AM         Hz         2100         1750 ~ 2500           Lower Frequency         : AM         Hz         3500         2500 ~ 6500           Lower Frequency         : AM         Hz         450         250 ~ 650           Cross Modulation, RS Standard         : AM         dB         60         50           Adjacent Channel Selectivity (10 kHz)         : AM         dB         70         60           Maximum Audio Output Power         : AM         W         4         3           Audio Output Power at 10% THD         : AM         W         3         2.5           THD at 500 mW Audio Output         : AM         %         3         6           M8:         1 mV Input, 30% modulation         : AM         %         5         8           SSB:         1 mV Input, 1 kHz, single-tone         : SSB         %         3         6           SSR         : AM         dB         40         30 ~ 60         \$           SSB:         1 mV Input, 1 kHz, single-tone         : SSB         dB         40         30 ~ 60           SSB         : SSB         dB         40         30 ~ 60         \$         \$           <					-
Upper Frequency         : AM SSB         Hz Hz         2100 3500         1750 ~ 2500 2500 ~ 5000           Lower Frequency         : AM SSB         Hz Hz         450 450         250 ~ 650 250 ~ 650           Cross Modulation, RS Standard         : AM dB         dB         60         50           Adjacent Channel Selectivity (10 kHz)         : AM SSB         dB         70         60           Maximum Audio Output Power         : AM SSB         W         4         3           Audio Output Power at 10% THD         : AM SSB         W         3         2.5           THD at 500 mW Audio Output AM: 1 mV Input, 30% modulation         : AM SM         %         3         6           SSB:         1 mV Input, 1 kHz, Single-tone         : SSB         %         3         6           SSB         dB         40         30 ~ 60         30 ~ 60         30 ~ 60           S/N Ratio at 1 mV Input         : AM         dB         40         34         34           Squelch Sensitivity at Threshold         : AM SSB         dB         40         34         34           Syster         : AM         dB         40         34         34           Syster         : AM         dB         40         34	Querell Audia Eidelity et 6 dB Deur	550	uв	10	10
SSB         Hz         3500         2500 ~ 5000           Lower Frequency         : AM         Hz         450         250 ~ 650           Cross Modulation, RS Standard         : AM         dB         60         50           Adjacent Channel Selectivity (10 kHz)         : AM         dB         70         60           Maximum Audio Output Power         : AM         W         4         3           Audio Output Power at 10% THD         : AM         W         3         2.5           THD at 500 mW Audio Output         : AM         W         3         2.5           THD at 500 mW Audio Output         : AM         %         3         6           SSB         : M         %         3         6           SSB:         : I mV Input, 30% modulation         : AM         %         5         8           SSB:         : I mV Input, 1 kHz, Single-tone         : SSB         dB         40         30 ~ 60           SVN         : SSB         dB         40         30 ~ 60         30         6           SSB         : B         : M         dB         40         30 ~ 20         60           SSB         : B         : M         : M         B		· • •	Н-7	2100	1750 ~ 2500
Lower Frequency         : AM SSB         Hz Hz         450 450 450 250 ~ 650           Cross Modulation, RS Standard         : AM         dB         60         50           Adjacent Channel Selectivity (10 kHz)         : AM         dB         70         60           Maximum Audio Output Power         : AM         dB         70         60           Maximum Audio Output Power         : AM         W         4         3           Audio Output Power at 10% THD         : AM         W         3         2.5           THD at 500 mW Audio Output         : AM         W         3         2.5           THD at 500 mW Audio Output         : AM         %         3         6           RF Gain Control Range at Max.         : SSB         %         3         6           SSB         : AM         dB         40         30 ~ 60           S/N Ratio at 1 mV Input         : AM         dB         40         34           Suelch Sensitivity at Threshold         : AM         #B         40         34           Squelch Sensitivity at Threshold         : AM         #B         40         34           SSB         : AM         #B         76         66	Opper frequency				
SSBHz450250 ~ 650Cross Modulation, RS Standard: AMdB6050Adjacent Channel Selectivity (10 kHz): AMdB7060Maximum Audio Output Power: AMW43Audio Output Power at 10% THD: AMW32.5SSBW32.5558W3Audio Output Power at 10% THD: AMW32.5THD at 500 mW Audio Output: AM%58SSB: 1 mV Input, 30% modulation: AM%58SSB: 1 mV Input, 1 kHz, Single-tone: SSB%36RF Gain Control Range at Max.: SSBdB4030 ~ 60SSBdB4030 ~ 60558dB40Syster type: AMdB4034Squelch Sensitivity at Threshold: AM $\mu V$ 0.52S Meter Sensitivity at "S-9" (No Modulation AM): AM $\mu V$ 10050 ~ 200SSBdB7666558dB761/2 IF Rejection Ratio, fo+10.695 MHz/2: AMdB9080IF Rejection Ratio, 10.695 MHz: AMdB9080IF Rejection Ratio, 10.695 MHz: AMdB8575					
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	Lower requency				
Adjacent Channel Selectivity (10 kHz)       : AM       dB       70       60         Maximum Audio Output Power       : AM       W       4       3         Audio Output Power at 10% THD       : AM       W       3       2.5         THD at 500 mW Audio Output       : AM       W       3       2.5         THD at 500 mW Audio Output       : AM       %       3       6         AM:       1 mV Input, 30% modulation       : AM       %       5       8         SSB       : 1 mV Input, 1 kHz, Single-tone       : SSB       %       3       6         SSB       : AM       %       5       8       8       6         SSB:       1 mV Input, 1 kHz, Single-tone       : SSB       %       3       6         SSB       : AM       6B       40       30 ~ 60       30       6         SSB       : AM       dB       40       34       34       36         Syss       : AM       dB       40       34       34       36         Syss       : AM       dB       40       34       34       36       36       36       36       30 ~ 200       35       2       35       36	Cross Modulation BS Standard				
SSBdB7060Maximum Audio Output Power: AMW43Audio Output Power at 10% THD: AMW32.5SSBW32.5THD at 500 mW Audio Output: AMW32.5AM:1 mV Input, 30% modulation: AM%36SSB:1 mV Input, 30% modulation: AM%58SSB:1 mV Input, 1 kHz, Single-tone: SSB%36RF Gain Control Range at Max.::Sensitivity Level: AMdB4030 ~ 60S/N Ratio at 1 mV Input: AMdB4034Squelch Sensitivity at Threshold: AM $\mu V$ 0.52S Meter Sensitivity at "S-9" (No Modulation AM): AM $\mu V$ 10050 ~ 200Image Rejection Ratio, fo+(2x10.695 MHz): AMdB76661/2 IF Rejection Ratio, fo+10.695 MHz/2: AMdB9080IF Rejection Ratio, 10.695 MHz/2: AMdB9080IF Rejection Ratio, 10.695 MHz/2: AMdB9080IF Rejection Ratio, 10.695 MHz/2: AMdB9080					
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	Adjacent Channel Selectivity (10 kHz)				
SSBW43Audio Output Power at 10% THD: AMW32.5SSBW32.5THD at 500 mW Audio OutputAM:1 mV Input, 30% modulation: AM%3680% modulation: AM%58SSB:1 mV Input, 1 kHz, Single-tone: SSB%36RF Gain Control Range at MaxSensitivity Level: AMdB4030 ~ 60SSBdB4030 ~ 60SVN Ratio at 1 mV Input: AMdB4034Squelch Sensitivity at Threshold: AM $\mu V$ 0.52S Meter Sensitivity at "S-9" (No Modulation AM): AM $\mu V$ 10050 ~ 200Image Rejection Ratio, fo+(2x10.695 MHz): AMdB76661/2 IF Rejection Ratio, fo+10.695 MHz/2: AMdB9080IF Rejection Ratio, 10.695 MHz: AMdB8575					
Audio Output Power at 10% THD       : AM SSB       W       3       2.5         THD at 500 mW Audio Output AM: 1 mV Input, 30% modulation       : AM       %       3       6         SSB:       1 mV Input, 30% modulation       : AM       %       5       8         SSB:       1 mV Input, 1 kHz, Single-tone       : SSB       %       3       6         RF Gain Control Range at Max. Sensitivity Level       : AM       dB       40       30 ~ 60         S/N Ratio at 1 mV Input       : AM       dB       40       34         Squelch Sensitivity at Threshold       : AM       dB       40       34         Squelch Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ 0.5       2         S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ 000       50 ~ 200         Image Rejection Ratio, fo+(2x10.695 MHz)       : AM       dB       76       66         1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       90       80	Maximum Audio Output Power				3
SSB       W       3       2.5         THD at 500 mW Audio Output					
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Audio Output Power at 10% THD			3	
AM:       1 mV Input, 30% modulation       : AM       %       3       6         80% modulation       : AM       %       5       8         SSB:       1 mV Input, 1 kHz, Single-tone       : SSB       %       3       6         RF Gain Control Range at Max.       :       Sensitivity Level       : AM       dB       40       30 ~ 60         S/N Ratio at 1 mV Input       : AM       dB       40       34       34         Squelch Sensitivity at Threshold       : AM       dB       40       34         Squelch Sensitivity at Threshold       : AM $\mu V$ 0.5       2         S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ 0.5       2         S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ 100       50 ~ 200         Image Rejection Ratio, fo+(2x10.695 MHz)       : AM       dB       76       66         1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       85       75		22R	vv	3	2.5
80% modulation: AM%58SSB: 1 mV Input, 1 kHz, Single-tone: SSB%36RF Gain Control Range at MaxSensitivity Level: AMdB4030 ~ 60SSBdB4030 ~ 60S/N Ratio at 1 mV Input: AMdB4034Squelch Sensitivity at Threshold: AM $\mu V$ 0.52S Meter Sensitivity at Threshold: AM $\mu V$ 0.52S Meter Sensitivity at "S-9" (No Modulation AM): AM $\mu V$ 10050 ~ 200SSBdB76661/2 IF Rejection Ratio, fo+10.695 MHz/2: AMdB9080IF Rejection Ratio, 10.695 MHz: AMdB8575			0/	0	•
SSB:       1 mV Input, 1 kHz, Single-tone       : SSB       %       3       6         RF Gain Control Range at Max. Sensitivity Level       : AM       dB       40 $30 \sim 60$ S/N Ratio at 1 mV Input       : AM       dB       40 $30 \sim 60$ S/N Ratio at 1 mV Input       : AM       dB       40 $34$ Squelch Sensitivity at Threshold       : AM $\mu V$ $0.5$ $2$ S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ $0.5$ $2$ S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ $100$ $50 \sim 200$ Image Rejection Ratio, fo+(2x10.695 MHz)       : AM       dB $76$ $66$ 1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM       dB $90$ $80$ IF Rejection Ratio, 10.695 MHz       : AM       dB $90$ $80$				3	
RF Gain Control Range at Max.       Sensitivity Level       : AM       dB       40 $30 \sim 60$ SSB       dB       40 $30 \sim 60$ S/N Ratio at 1 mV Input       : AM       dB       40 $34$ Squelch Sensitivity at Threshold       : AM $\mu V$ $0.5$ $2$ S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ $0.5$ $2$ S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ $100$ $50 \sim 200$ Image Rejection Ratio, fo+(2x10.695 MHz)       : AM       dB       76       66         1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       90       80					
Sensitivity Level       : AM       dB       40 $30 \sim 60$ S/N Ratio at 1 mV Input       : AM       dB       40 $30 \sim 60$ S/N Ratio at 1 mV Input       : AM       dB       40 $34$ Squelch Sensitivity at Threshold       : AM $\mu V$ $0.5$ $2$ S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ $0.5$ $2$ S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ $100$ $50 \sim 200$ Image Rejection Ratio, fo+(2x10.695 MHz)       : AM       dB       76 $66$ 1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM       dB       90 $80$ IF Rejection Ratio, 10.695 MHz       : AM       dB $90$ $80$		: SSB	%	3	6
SSBdB40 $30 \sim 60$ S/N Ratio at 1 mV Input: AM SSBdB4034Squelch Sensitivity at Threshold: AM SSB $\mu V$ 0.52S Meter Sensitivity at "S-9" (No Modulation AM): AM SSB $\mu V$ 0.00 $50 \sim 200$ S Meter Sensitivity at "S-9" (No Modulation AM): AM SSB $\mu V$ 100 $50 \sim 200$ Image Rejection Ratio, fo+(2x10.695 MHz): AM SSBdB76661/2 IF Rejection Ratio, fo+10.695 MHz/2: AM SSBdB9080IF Rejection Ratio, 10.695 MHz: AM SAMdB8575			10	40	00 00
S/N Ratio at 1 mV Input       : AM SSB       dB dB       40 40       34 34         Squelch Sensitivity at Threshold       : AM SSB $\mu V$ $\mu V$ 0.5 0.5       2 2         S Meter Sensitivity at "S-9" (No Modulation AM)       : AM SSB $\mu V$ $\mu V$ 100 100       50 ~ 200 50 ~ 200         Image Rejection Ratio, fo+(2x10.695 MHz)       : AM SSB       dB dB       76 66       66 66         1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM SSB       dB dB       90 	Sensitivity Level				
SSB       dB       40       34         Squelch Sensitivity at Threshold       : AM $\mu$ V       0.5       2         S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu$ V       100       50 ~ 200         Image Rejection Ratio, fo+(2x10.695 MHz)       : AM       dB       76       66         1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       85       75	C/N Detie et 1 m// la mot				
Squelch Sensitivity at Threshold: AM SSB $\mu V$ $\mu V$ 0.5 0.52 2S Meter Sensitivity at "S-9" (No Modulation AM): AM SSB $\mu V$ $\mu V$ 100 10050 ~ 200 50 ~ 200Image Rejection Ratio, fo+(2x10.695 MHz): AM SSBdB dB76 7666 661/2 IF Rejection Ratio, fo+10.695 MHz/2: AM SSBdB dB90 8080 80IF Rejection Ratio, 10.695 MHz: AM SSBdB dB90 75	S/IN Ratio at 1 mV input				
SSB $\mu V$ 0.5       2         S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ 100       50 ~ 200         Image Rejection Ratio, fo+(2x10.695 MHz)       : AM       dB       76       66         1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       85       75	Concellate Consideration of Threads and				
S Meter Sensitivity at "S-9" (No Modulation AM)       : AM $\mu V$ 100 $50 \sim 200$ Image Rejection Ratio, fo+(2x10.695 MHz)       : AM       dB       76       66         1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       85       75	Squeich Sensitivity at Inreshold				
SSB $\mu$ V10050 ~ 200Image Rejection Ratio, fo+(2x10.695 MHz): AMdB76661/2 IF Rejection Ratio, fo+10.695 MHz/2: AMdB9080IF Rejection Ratio, 10.695 MHz: AMdB8575					
Image Rejection Ratio, fo+(2x10.695 MHz)       : AM       dB       76       66         1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       90       80	S meter Sensitivity at "5-9" (No Modulation AM)				
SSB       dB       76       66         1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM       dB       90       80         SSB       dB       90       80         SSB       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       85       75					
1/2 IF Rejection Ratio, fo+10.695 MHz/2       : AM       dB       90       80         SSB       dB       90       80         IF Rejection Ratio, 10.695 MHz       : AM       dB       85       75	Image Rejection Ratio, fo+(2x10.695 MHz)				
SSB         dB         90         80           IF Rejection Ratio, 10.695 MHz         : AM         dB         85         75					
IF Rejection Ratio, 10.695 MHz : AM dB 85 75	1/2 IF Rejection Ratio, to+10.695 MHZ/2				
	TF Rejection Ratio, 10.695 MHz				
Oscillator Drop-out Voltage : AM V 9 11 SSB V 9 11	Oscillator Drop-out Voltage				
			-		
Clarifier Range : AM kHz $\pm 1.25 \pm 0.6 \sim \pm 2.5$	Clarifier Range				
SSB kHz $\pm 1.25 \pm 0.6 \sim \pm 2.5$					
Spurious Rejection Ratio In band : AM dB 65 56	Spurious Rejection Ratio In band				
SSB dB 65 56					
Out of Band : AM dB 60 50	Out of Band				
SSB dB 60 50		22R	qR	60	50

### **RECEIVER:**(ANL & Noise Blanker Switch OFF)

		UNIT	NOMINAL	LIMIT
Battery Drain at No Signal	: AM	mA	250	500
	SSB	mA	250	500
Battery Drain at Maximum Output Power	: AM SSB	mA mA	1000 1000	1500 1500
PUBLIC ADDRESS:				
Microphone Sensitivity for 3W Output Power at 1 kHz		mV	1.5	3
Maximum Output Power		W	4	3
TRANSMITTER:				
Frequency Tolerance at 25°C (5 Minutes after switch on)	: AM SSB	% %	±0.0005 ±0.0005	±0.003 ±0.003
Carrier Power at No Modulation	: AM	W	3.8	3.5 - 4.4
PEP Power, Two Tone	: SSB	W PEP	12	10 - 13.2
Modulation Distortion at 1 kHz, 80% Modulation	: AM	%	3	8
Spurious Harmonic Emission	: AM SSB	dB dB	-65 -65	-60 -60
Carrier Suppression	: SSB	dB	-55	-40
Unwanted Sideband Suppression at 2.5 kHz	: SSB	dB	-55	-40
Modulation Frequency Response at -6 dB Down (1 kHz, 0 dB reference)				
Lower Frequency	: AM SSB	Hz Hz	450 450	$\begin{array}{l} 250 \sim 650 \\ 250 \sim 650 \end{array}$
Upper Frequency	: AM SSB	Hz Hz	2500 3500	$2000 \sim 4000$ $2000 \sim 5000$
Carrier Power Uniformity, Ch-to-Ch at No Modulation	: AM	W	0.3	0.4
Mic Input Level Uniformity, Ch-to-Ch for 4 watts Output 2.5 kHz Single Tone, SSB		dB	2	3
Mic Input Level Uniformity, LSB to USB for 4 watts Output, 1.5 kHz Single Tone		dB	1	3
Microphone Sensitivity AM: For 50% Modulation SSB: For 4 watts PEP	: AM : SSB	mV mV	0.4 0.4	1.0 1.0
AMC Range AM: $50 \sim 100\%$ Modulation SSB: $10 \sim 13.2$ watts PEP	: AM SSB	dB dB	60 60	40 40
Battery Drain at No Modulation	: AM SSB	mA mA	2200 500	3000 1000
Battery Drain	330	ША	500	1000
AM: Max. Modulation SSB: Max watts PEP, Two tone	: AM SSB	mA mA	2200 2000	3000 3000

Note; Nominal Specs represent the design specs; all units should be able to approximate these, some will exceed and some may drop slightly below these specs.

Limit Specs represent the absolute worst condition which still might be considered acceptable, in no case should a unit perform to less than within any Limit Spec.

## 2. DISASSEMBLY INSTRUCTIONS

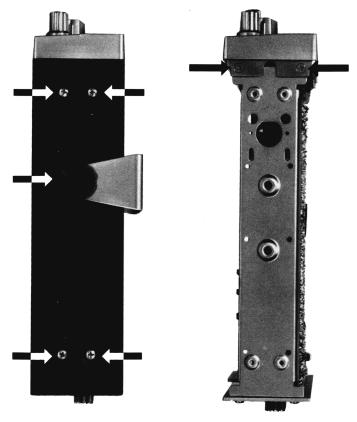
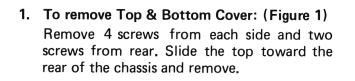
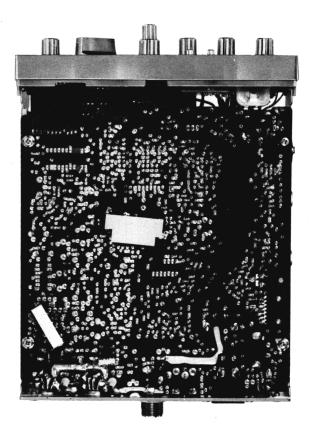


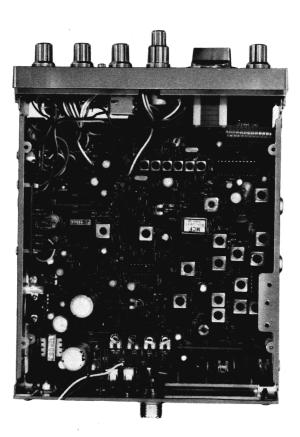
Figure 1

Figure 2

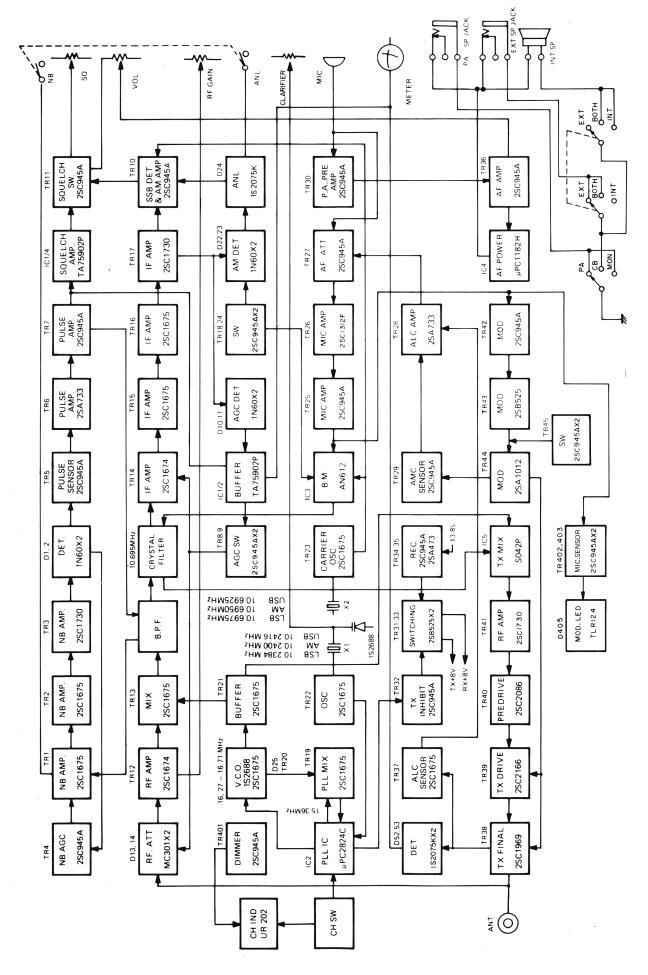


2. To remove Front Panel: (Figure 2) Remove 2 screws from each side.





### 3. BLOCK DIAGRAM



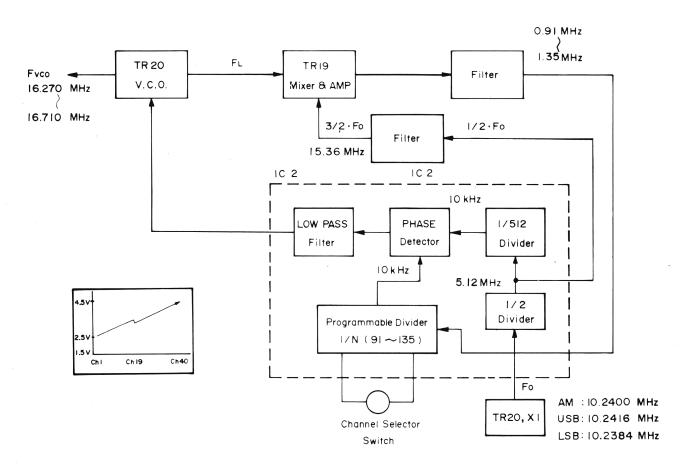
- 7 -

### 4. CIRCUIT DESCRIPTION

### 1. PLL

The PLL circuit (Phase Locked Loop) used in TRC-451 consists of 6 major components: VCO (Voltage Controlled Oscillator), 1/N Divider, Ref-

erence Oscillator, 1/1024 Divider, Phase Detector and Low Pass Filter.



The VCO is an Oscillator whose oscillation frequency varies in accordance with input voltage changes. 1/N Divider is a programmable Divider; the "N" is varied by the Channel Selector Switch. A portion of the VCO output is mixed with a signal from TR22 by TR19, "In-Loop mixer". It is used to shift the VCO frequency. TR22, "In-Loop Local Oscillator", generates 10.24 MHz frequency (AM: 10.2400 MHz, USB: 10.24116 MHz and LSB: 10.2384 MHz). This 10.24 MHz signal is fed to TR19, Mixer, passing through the 1/2 Divider and Filter. VCO frequency is down mixed with a signal from Tripler providing 0.91 MHz through 1.35 MHz (see frequency table). The signal is fed to the 1/N Divider through the Filter. The Filter eliminates harmonics. 1/N Divider produces the 10 kHz frequency and it is fed to the Phase Detector.

Meanwhile, the 10.24 MHz frequency generated by X1, is changed to 10 kHz by 1/1024 Divider and is fed to another input of the Phase Detector. Thus the Phase Detector receives two signals (both 10 kHz). It compares the phase difference of the two and generates an error voltage which acts on the VCO to bring the two frequencies exactly inphase. When this condition occurs, the PLL circuit is "Locked". A Low Pass Filter is used to change the AC signal to DC.

Then the VCO output is up-mixed with Local Oscillator frequency (X2 and TR23) and the resulting 27 MHz frequencies are transmitted.

By varying the constant N, the output frequency from the VCO can be varied in 10 kHz steps. The constant N is controlled by the Channel Selector Switch. A frequency shift of 2.5 kHz (required for AM, USB and LSB) is obtained by switching Diodes D29 (LSB), D28 (USB) and D27 (AM).

### 2. LOCAL OSCILLATOR (CARRIER OSCILLATOR)

TR23 is a carrier oscillator which generates 10.6925 MHz, 10.6975 MHz or 10.6950 MHz.

In USB mode, X2 functions by D35 switching; so TR23 oscillates on 10.6925 MHz.

In LSB mode, X2 functions by D36 switching and TR23 oscillates on 10.6975 MHz.

In AM mode, when the unit is in transmitting, X2 functions by D34 switching and also TR21 oscillates on 10.6950 MHz.

Therefore TR23 oscillates on 10.6950 MHz when receiving an AM modes.

The carrier output goes to the receiver circuit for demodulation of SSB signal or goes to transmitter circuit for modulation.

### 3. CHANNEL SELECTION PROGRAM

The Divide Ratio N, is determined by voltage supplied to the program input terminals, pins No. 1 through 6 of IC2. The function of the program input terminals is shown in Frequency Table chart. For example, when the unit is transmitting on Channel 19, the frequencies will be as shown in following table:

	AM mode	USB mode	LSB mode
N	113	113	113
Fo x ½ x 3 (MHz)	15.360	15.360	15.360
N x 10 kHz (MHz) output of TR19	1.130	1.130	1.130
F∟ VCO Frequency (MHz)	16.490	16.490	16.470
FIF (MHz) Local Oscillator Frequency	10.695	10.695	10.695
Ft Transmit Fre- quency (MHz)	27.185	27.185	27.185

### FREQUENCY TABLE OF PLL

СН	ANT. Frequency	Divide Ratio	1/N INPUT FREQUENCY	PROGRAM CODE (PIN NO. OF IC2)							LOCAL OSC UT FREQUEN	(MHz) JCY
	(MHz)	"N"	(MHz)	1	2	3	4	5	6	AM.RX&TX	USB	LSB
1	26.965	91	0.91	1	0	0	0	0	0	16.270	16.2725	16.2675
2	26.975	92	0.92	0	1	0	0	0	0	16.280	16.2825	16.2775
3	26.985	93	0.93	1	1	0	0	0	0	16.290	16.2925	16.2875
4	27.005	95	0.95	0	0	1	0	0	0	16.310	16.3125	16.3075
5	27.015	96	0.96	1	0	1	0	0	0	16.320	16.3225	16.3175
6	27.025	97	0.97	0	1	1	0	0	0	16.330	16.3325	16.3275
7	27.035	98	0.98	1	1	1	0	0	0	16.340	16.3425	16.3375
8	27.055	100	1.00	0	0	0	1	0	0	16.360	16.3625	16.3575
9	27.065	101	1.01	1	0	0	1	0	0	16.370	16.3725	16.3675
10	27.075	102	1.02	0	0	0	0	1	0	16.380	16.3825	16.3775
11	27.085	103	1.03	1	0	0	0	1	0	16.390	16.3925	16.3875
12	27.105	105	1.05	0	1	0	0	1	0	16.410	16.4125	16.4075
13	27.115	106	1.06	1	1	0	0	1	0	16.420	16.4225	16.4175
14	27.125	107	1.07	0	0	1	0	1	0.	16.430	16.4325	16.4275
15	27.135	108	1.08	1	0	1	0	1	0	16.440	16.4425	16.4375
16	27.155	110	1.10	0	1	1	0	1	0	16.460	16.4625	16.4575
17	27.165	111	1.11	1	1	1	0	1	0	16.470	16.4725	16.4675
18	27.175	112	1.12	0	0	0	1	1	0	16.480	16.4825	16.4775
19	27.185	113	1.13	1	0	0	1	1	0	16.490	16.4925	16.4875
20	27.205	115	1.15	0	0	0	0	0	1	16.510	16.5125	16.5075
21	27.215	116	1.16	1	0	0	0	0	1	16.520	16.5225	16.5175
22	27.225	117	1.17	0	1	0	0	0	1	16.530	16.5325	16.5275
23	27.255	120	1.20	1	1	0	0	0	1	16.560	16.5625	16.5575
24	27.235	118	1.18	0	0	1	0	0	1	16.540	16.5425	16.5375
25	27.245	119	1.19	1	0	1	0	0	1	16.550	16.5525	16.5475
26	27.265	121	1.21	0	1	1	0	0	1	16.570	16.5725	16.5675
27	27.275	122	1.22	1	1	1	0	0	1	16.580	16.5825	16.5775
28	27.285	123	1.23	0	0	0	1	0	1	16.590	16.5925	16.5875
29	27.295	124	1.24	1	0	0	1	0	1	16.600	16.6025	16.5975
30	27.305	125	1.25	0	0	0	0	1	1	16.610	16.6125	16.6075
31	27.315	126	1.26	1	0	0	0	1	1	16.620	16.6225	16.6175
32	27.325	127	1.27	0	1	0	0	1	1	16.630	16.6325	16.6275
33	27.335	128	1.28	1	1	0	0	1	1	16.640	16.6425	16.6375
34	27.345	129	1.29	0	0	1	0	1	1	16.650	16.6525	16.6475
35	27.355	130	1.30	1	0	1	0	1	1	16.660	16.6625	16.6575
36	27.365	131	1.31	0	1	1	0	1	1	16.670	16.6725	16.6675
37	27.375	132	1.32	1	1	1	0	1	1	16.680	16.6825	16.6775
38	27.385	133	1.33	0	0	0	1	1	1	16.690	16.6925	16.6875
39	27.395	134	1.34	1	0	0	1	1	1	16.700	16.7025	16.6975
40	27.405	135	1.35	0	0	0	0	0	0	16.710	16.7125	16.7075

0 = Low level (0 - 1.0 volt)

1 = High level (3.5 - 6 volts)

## 5. ABBREVIATED CIRCUIT DESCRIPTION OF RECEIVER

### 1. RF Stage

A signal from the antenna is fed to RF Amplifier, TR12. The signal is processed to Mixer, TR13. The signal is mixed with a signal from the VCO (approx. 16 MHz) by TR21 and a 10.7 MHz signal (IF frequency) is produced.

### 2. IF Stage

The 10.7 MHz signal is amplified by T14 through TR17.

In the AM mode, the signal is detected by D22 and D23, and passed on to TR10, AF amplifier.

In the SSB modes, the signal is fed to TR10. TR10 operates as a Demodulator in SSB modes. To demodulate the SSB signal, the 10.7 MHz signal is needed. The AF signal then goes to IC4 through TR36, AF Power Amp.

#### 3. AF Stage

The signal from TR10 is amplified by TR36, AF Pre-Amp, and IC4, AF Power amplifier. The output is heard from the Speaker.

#### 4. AGC

IC1 is an AGC amplifier. A portion of the IF signal is amplified by IC1 and processed to TR14, which adjusts the gain of TR14. The signal also is applied to an RF attenuator consisting of D13 and D14.

### 5. Squelch

A portion of IC1's output goes to the squelch circuit. The squelch circuit consists of TR11; the output of IC1 is used to cut off TR11.

#### 6. Fine Tuning

In the Receive mode, the output of X1 is varied in frequency by D30, Varactor Diode, and Fine Tuning VR403.

In the Transmit mode, the voltage to D30 is fixed by VR3, so the frequency is stable.

### 7. ANL

The ANL circuit consists of D24 and related circuits. The ANL circuit is effective on AM mode only. ANL is a clipping circuit; the clipping level is automatically determined by the carrier voltage.

#### 8. Noise Blanker

A signal, including noise signal components from the antenna, is converted to the 10.7 MHz IF frequency by TR13 and fed to TR1. The 10.7 MHz signal, including noise, is amplified by TR1, 2 and TR3 and then detected by D1 and D2. The detected signal is fed to TR5, Sensor, which discriminates only a pulse-type noise from the signal. The pulse-type noise is amplified by TR6 and drives TR7 "on". Therefore, if noise exists, TR7 turns "on" and noise is reduced.

TR4 provides NB AGC, so that the noise blanker output is reduced or eliminated in the presence of a strong signal.

### 9. Transmit/Receive Control

TX/RX is controlled by pin 1, 3 and pin 5 of MIC jack. When pin 5 is shorted to pin 1, the unit is in Receive. If pin 3 is shorted to pin 1, the unit is in Transmit.

If pin 5 of MIC Jack becomes low, the DC voltage appears on collector of TR31. Collector of TR31 goes to B + of Receiver Circuit.

If pin 3 of MIC Jack becomes low, the DC voltage appears on collector of TR33. Collector of TR33 goes to TX circuit.

### 6. ABBREVIATED CIRCUIT DESCRIPTION OF TRANSMITTER

### 1. AM

An AF signal from the Mic is fed to TR26 through TR27. This signal is amplified by TR26 and TR25, Mic Amp, and is fed to TR42 and TR43. The signal amplified by TR44 is applied to TR39 and TR38 for modulation.

For the RF portion, two signals are mixed by IC5, Mixer, with a 27 MHz signal being produced. [One of these signals is 10.7 MHz which is generated by TR23 and other signal is the VCO output (approx. 16 MHz).] The 27 MHz signal is amplified by TR41 and TR40. The signal is amplified and modulated by TR39 and TR38 and is delivered to the Antenna. A portion of the signal is detected by D52 and D53 and Drives the RF PWR meter.

### 2. SSB

The audio signal from Mic is amplified by TR26 and TR25, it then is applied to IC3, Balanced Modulator. The carrier signal (10.6925 for USB or 10.6975 MHz for LSB) is applied to the other input of IC3. IC3 produces a carrier-suppressed DSB signal. The DSB signal is converted into SSB by FL1, Filter. In the USB mode, carrier + audio signal is produced. And in the LSB mode, carrier audio signal is produced.

Example: In the USB mode, if 1 kHz audio signal modulates the carrier signal, two signals are produced as produced as shown below:

10.6925 MHz + 1 kHz = 10.6935 MHz

But the 10.6925 MHz is suppressed by FL1, because the bandwidth of the FL1 is within  $\pm 2.5$  kHz of 10.6950 MHz.

The SSB signal is converted to 27 MHz signal by IC5. IC5 is a Mixer, and mixes the SSB signal with the VCO output of PLL.

The resulting SSB signal is amplified by TR41, 40, 39 and TR38 and is delivered to the Antenna.

### 3. AMC CIRCUIT

TR29 is a detector for AMC and the Input Attenuator consists of R157 and TR27. In an over-modulation condition, TR29 turns on and the detected current flows into R153. This current drives TR28 and TR27. As the C-E impedance of TR27 lowers, the input signal is lowered. The AMC circuit is not effective in SSB modes.

### 4. ALC CIRCUIT

TR37 is an ALC detector which detects peak RF power. If the power level exceeds a level that is selected by VR6, TR28 drives TR27 to decrease the input audio signal. ALC is effective only on SSB modes. In AM mode, the emitter voltage of TR37 is pulled up to B+, and thus the ALC circuit is inoperative.

### 5. UNLOCK DETECTOR

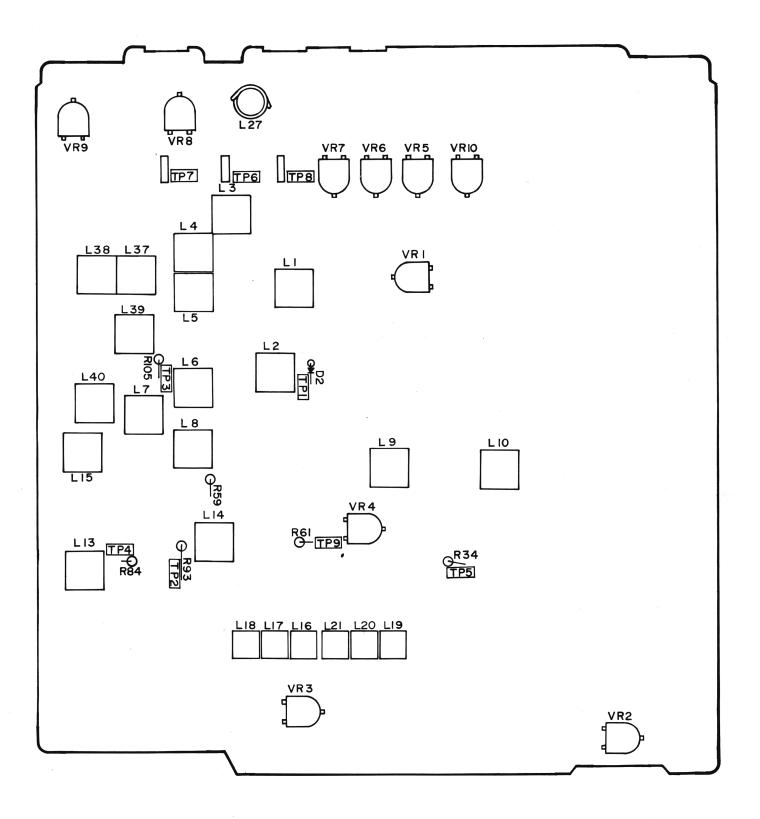
TR33 is provided to shut off the Transmit output if the PLL is unlocked. TR33 is provided to turn off TR32.

In an unlocked condition, pin 15 of IC2 goes low.

### 6. PUBLIC ADDRESS

A signal from the Mic is amplified by TR30 is passed on through TR401. TR36 amplifies the signal, which then is applied to IC4 where it is further amplified before output to the PA speaker.

# 7. ALIGNMENT INSTRUCTIONS



### ALIGNMENT OF PLL AND CARRIER OSCILLATOR

### 1. Test Equipment required:

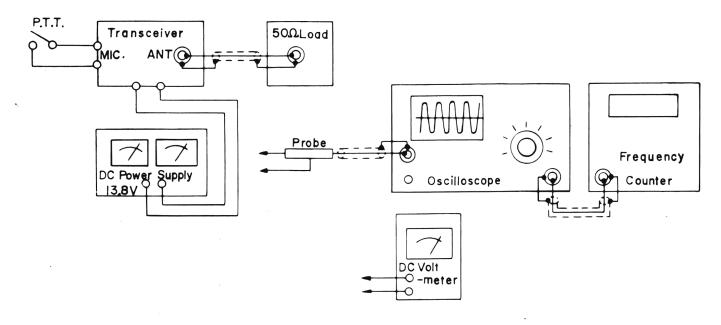
- a. Oscilloscope (DC 50 MHz)
- b. Frequency Counter (0 30 MHz)
- c. DC Power Supply
- d. 50 ohm Load

### 2. Alignment Procedure:

Connect test equipment as shown below.

STEP	PRESET TO	CONNECTION	ADJUSTMENT
1	CH: 40, AM, RX, Clarifier in center	TP-2	Adjust L-14 for 4.5V DC reading on Oscilloscope. (Oscilloscope in DC mode)
2	Same as step 1. CH: 1.	TP-2	Check that the voltage is more than 2V DC on Oscilloscope.
3	Same as step 1. CH: 19, USB, RX	TP-4	Adjust L-13 for maximum reading on Oscilloscope. (Oscilloscope in AC mode).
4	Same as step 3.	TP-3	Adjust L-15 for maximum reading on Oscilloscope.
5	Same as step 3.	TP-3	Adjust L-17 for 16.4925 MHz ±20 Hz
6	Same as step 1. CH: 19, AM, RX	TP-1	Adjust L-16 for 16.4900 MHz ±20 Hz
7	Same as step 1. CH: 19, LSB, RX	TP-1	Adjust L-18 for 16.4875 MHz ±20 Hz
8	Same as step 1. CH: 19, LSB, TX.	TP-1	Adjust VR-3 for 16.4875 MHz ±20 Hz
9	Same as step 1. CH: 19, LSB, RX.	TP-5	Adjust L-20 for 10.6925 MHz <sup>+0</sup> <sub>-5</sub> Hz
10	Same as step 1. CH: 19, USB, RX.	TP-5	Adjust L-21 for 10.6975 MHz <sup>+5</sup> _0Hz
11	Same as step 1. CH: 19, TX, AM. Disconnect TP-6, TP-7, TP-8	TP-9	Adjust L-19 for 10.6950 MHz ±5Hz

### PLL AND CARRIER OSCILLATOR TEST EQUIPMENT SETUP



### ALIGNMENT OF RECEIVER SECTION

### 1. Equipment Required:

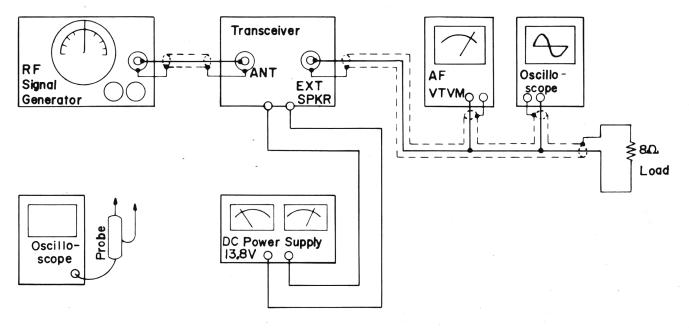
- a. RF Signal Generator (27 MHz Band, 50 ohm output impedance)
- b. AF VTVM
- c. Oscilloscope (For AF Signal)
- d. DC Power Supply
- e. 8 ohm Load
- f. Oscilloscope (0 50 MHz)

### 2. Procedure

Connect Test Equipment as shown below.

STEP	PRESET TO	ADJUSTMENT	PROCEDURE
1	Channel : 19 Clarifier : center Volume : fully CW. RF GAIN : fully CW. Squelch : fully CCW. NB/ANL : off Mode : AM		Set the SG on channel 19, 27.185 MHz with 1 kHz, 30% modulation.
2	Same as step 1	L10,9,8,7,6,5,4 and 3.	Adjust the level of SG to obtain 2V reading on AF VTVM. Then adjust coils for maximum reading on AF VTVM. Repeat this step reducing the SG output.
3	Same as step 1	L3	Adjust L3 for max. reading on AF VTVM. Check the sensitivity difference between CH1 and 40. If it is over 1 dB, re-adjust L3 to obtain within 1 dB.
4	Same as step 1 except squelch is fully CW.	VR2	Set the level of SG to 1000 $\mu$ V. Then adjust VR2 so that the AF signal will just appear on Oscilloscope.
5	Same as step 1	VR1	Set the level of SG to 100 $\mu$ V. Then adjust for "S-9" reading on Transceiver's meter.
6	Same as step 1 except NB/ANL switch is ON.	L1 and 2.	Connect the Oscilloscope to TP-1. Adjust the level of SG to approx. 1.6 $\mu$ V. Then adjust for max. DC reading.

### **RECEIVER TEST EQUIPMENT SETUP**



### ALIGNMENT OF TRANSMITTER SECTION

### 1. Equipment Required:

- a. AF Oscillator (two required)
- b. AF VTVM (Full scale: 1V DC with RF probe)
- c. DC Ammeter
- d. RF Power Meter
- e. 50 ohm load and Attenuator

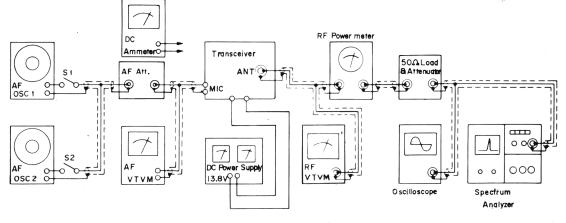
### 2. Alignment Procedure:

Connect test equipment as shown below.

- f. Oscilloscope
- g. RF VTVM
- h. Monitor Receiver or Spectrum Analyzer
- i. DC Power Supply (13.8 V/3 Amp.)

STEP	PRESET TO	ADJUSTMENT	REMARKS
1	CH: 19, PA/CB: CB USB mode, TX S1 and S2: OFF	VR9	Break circuit at TP8, and TP7 place DC mA meter in series. Adjust for 10 mA.
2	Same as step 1	VR8	Break circuit at TP8 and TP6, place DC mA meter in series. Adjust for 100 mA $^{+5}_{-0}$ mA.
	After STEPs 1 and 2,	restore circuit at TP8	and TP7.
3	Same as step 1 OSC1: 500 Hz OSC2: 2400 Hz S1,S2: ON	L40,39,38,37 and 27	Set VR6 to full CW rotation (ALC "off" condition). Keep the AF ATT for approx. 20V reading on RF VTVM. Then adjust coils for max. reading. Repeat this adjustment several times, reducing the AF input level to the microphone circuit.
4	Same as step 3	L40,39,38 and 37	Adjust Coils for max. reading on RF VTVM. Check the power difference between CH1 and CH40. If it is over 1V on RF VTVM, readjust coils to obtain within 1V.
5	Same as step 1 AM mode OSC1: 1 kHz S1: ON, S2: OFF	L27	Adjust level of OSC1 for 5 mV reading on AF VTVM, then adjust L27 for maximum reading on RF VTVM.
6	Same as step 1 S1, S2: OFF	VR4	Adjust for minimum carrier leakage for both USB and LSB on Spectrum Analyzer or Oscilloscope.
7	Same as step 3 OSC1: 500 Hz S1,S2: ON	VR6	Adjust OSC1 and OSC2 for 5 mV reading on AF VTVM, then adjust VR6 for 24.5V reading on RF VTVM.
8	Same as step 1 AM mode S1, S2: OFF	VR10	Adjust for 4.0W reading on RF Power meter.
9	Same as step 8	VR7	Adjust for "4W" reading on the Transceiver's meter.
10	Same as step 5	VR5	Adjust output of OSC1 for 200 mV reading on AF VTVM then adjust VR5 for 95 to 98% modulation on Scope.

### TRANSMITTER TEST EQUIPMENT SETUP



## 8. SEMICONDUCTOR VOLTAGE CHART

Measurement condition: Following voltages were measured with no signal input.

### IC1 TA75902P (SQ. CCW)

Pin No.	1	2	3	4	5	6	7	8	9	10
Voltage	7.2	0.6	0.7	8.5	0	0	0	0	3.0	2.2
								7.0		4.3
								(SQ.CW)		(SQ.CW)
Pin No.	11	12	13	14						
Voltage	0	0.3	0.3	0.8						

#### **IC2** µ**PD2824C**

Pin No.	1	2	3	4	5	6	7	8	9	10	11
Voltage	5.0	0	0	5.0	5.0	0	5.0	0	0	*	5.0
Pin No.	12	13	14	15	16	17	18	19	20	21	22
Voltage	2.6	2.6	*	5.0	5.0	3.4	3.4	3.3	0.2	0	2.4

#### IC3 AN612

Pin No.	1	2	3	4	5	6	7
Voltage	AM I	3.4	3.4	0	6.1	7.6	RX 7.8
Voltage	SSB 3.1						тх 4.0

#### **IC4** µ**PC1182H**

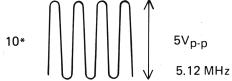
Pin No.	1	2	3	4	5	6	7
Voltage	0	1.9	1.2	0	6.8	12.7	13.7

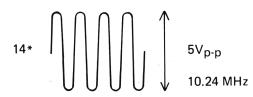
#### IC5 SO42P (TX ONLY)

Pin No.	1	2	3	4	5	6	7.	8	9	10
Voltage	0	8.0	8.0	0	8.0	0	2.8	2.8	0	0
Pin No.	11	12	13	14						
Voltage	0	0	0	0						

IC2.





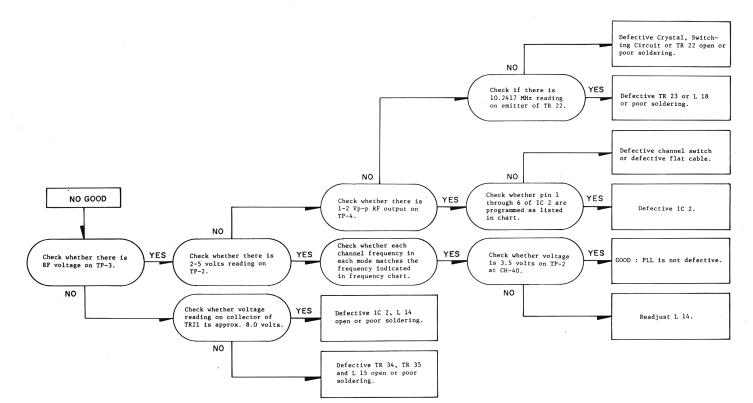


<b>BIPOLAR 1</b>	RANSIS	TOR
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					C
No.		Collector	Base		Remarks
TR 1	1.1	8.0	1.8	RX	SSB, NB: ON
2	0	2.8	0.7	RX	SSB, NB : ON
3	2.0	8.0	2.8	RX	SSB, NB : ON
4	1.1	8.4	0	RX	SSB, NB : ON
5	0	7.8	0	RX	SSB, NB : ON
6	8.4	0	7.8	RX	SSB, NB : ON
7	0	0	0	RX	SSB, NB : ON
8	0	0	0		AM
	0	0	0.7		SSB
9	0	0	0.7		AM
	0	0.7	0		SSB
10	0.2	7.5	0.7		
11	0	0	<b>0</b> (0.7)		SQ,CCW(SQ,CW)
12	1.7	8.0	2.5	RX	
13	0.2	8.2	0.8	RX	
14	0.9	8.4	1.6	RX	
	7.6	8.4	2.5	TX	
15	0	4.0	0.7	RX	
16	3.2	7.2	4.0	RX	
17	2.4	7.3	3.2	RX	
18	0	0	0.7		AM
	0	2.3	0		SSB
19	0.9	5.2	1.5		
20	1.7	8.1	2.4		
21	1.8	8.0	2.5		
22	2.6	7.2	3.3		
23	2.8	7.1	3.3		
24	0	0	0.7		AM
	0	3.1	0		SSB
25	1.2	2.8	1.9		
26	0.4	1.9	1.0		
27	0	0	0.6	RX	
	0	0	0	ТХ	
28	8.5	0.6	8.5	RX	
	8.5	0	8.5	ТХ	
29	4.3	8.5	1.1		
30					
				RX	
		0			
32					
33					
34					
30 31 32 33 33 34 35 36	1.8 8.5 8.4 8.5 5.1 0 8.5 8.4 1.0 13.7 0.2	3.7 8.4 0.3 0 8.0 0 0 8.3 13.0 8.5 3.9	2.4 7.7 7.9 8.5 5.1 0.7 7.9 7.6 1.6 13.0 0.8	RX TX PA RX TX RX TX	

No.	Emitter	Collector	Base	Remarks
TR37	0.6	8.5	0	
38	0	5.0	0.7	AM
	0	13.6	0.7	SSB
39	0	5.0	0.6	AM
	0	13.6	0.6	SSB
40	1.0	8.3	1.4	
41	0.8	8.3	1.4	
42	5.1	12.0	5.7	AM
	13.6	13.2	5.7	SSB
43	12.6	5.1	12.0	AM
	13.0	13.6	13.2	SSB
44	13.8	5.1	12.6	AM
	13.8	13.6	13.0	SSB
45	0	12.6	0	AM
	7.5	13.0	8.1	SSB
46	0	0	0.7	AM
	0	8.1	0	SSB

## 9. TROUBLESHOOTING HINTS



### PLL TROUBLESHOOTING HINTS

### UNIT WILL NOT TURN ON

- 1. Broken/defective DC Power cable.
- 2. Fuse blown. Be sure you check for the cause.
- 3. Defective power switch.
- 4. Defective wires or poor soldering in power supply circuit.

#### NO RECEIVE SOUND

- 1. Defective RF circuit in receiver.
- 2. Defective Noise Blanker.
- 3. Defective audio power IC, IC4. Check Voltage at pin 5 of IC4; if approximately 6V, problem is not with this IC.
- 4. Squelch is "ON" all the time.

If voltage at Base of TR11 is approx. OV with Squelch Control in fully CCW, problem is not with squelch circuit. Defective TR11.

5. Check whether the transceiver's signal strength meter deflects when a signal (27 MHz carrier with 1 kHz, 30% modulation, 100  $\mu$ V level) is applied to antenna.

a. The meter indicates "S-9".

You can assume that antenna through IF stage are OK.

NO AM ..... Checks should be made on Detector (D22 and 23) ANL circuit (D24), TR18 and AF stage (TR10, TR11, VR401, TR36 and IC-4).

NO SSB BUT AM OK ..... Check frequency and level on TP5, if no signal, checks should be made on X-tals and TR23.

NO SSB ..... Checks should be made on Detector, TR10, TR11 and AF stage, VR401, TR36 and IC4.

b. No deflecting of meter.

Checks should be made on RF stage (TR12 and TR13), IF stage (TR14, TR15, TR16 and TR17) or AGC circuit (D4, D10, D11 and IC1). Or trouble may be in PLL circuit. Check frequency on TP3; if it is as listed in Table, problem is not with PLL circuit.

- 6. Defective AGC circuit.
- 7. Defective PLL circuit.
- 8. Defective antenna connector.

### **NO NOISE**

- 1. Broken or bad contact in microphone connector and/or push-to-talk switch.
- 2. Defective RX power circuit.
- 3. Defective RX audio circuit.
- 4. Defective PLL circuit and/or channel switch.
- 5. Defective squelch.
- 6. Defective PA-CB switch.

### NO TRANSMISSION

- 1. Broken or bad contact in microphone connector and/or push-to-talk switch.
- 2. Broken or bad contact in antenna connector.
- 3. Defect in power supply.
- 4. Defect in PLL and/or Carrier Oscillator (Improper adjustment).
- 5. Inoperative microphone amplifier and/or ballanced modulator in SSB mode.
- 6. Check the frequency at TP3; carrier oscillation may have stopped; if no carrier, check TR23, D34,35,36 and X2.
- 7. Carrier is OK, but no TX; check the frequency at TP3. If not same as listed in Frequency Table, PLL circuit defective. If OK, check IC3,5, TR38,39,40 and 41.
- 8. If no TX on SSB modes and no modulation on AM mode. Mic amplifier or ALC/AMC section is defective. Check TR42,43,44,45 and 46.

### NO MODULATION

- 1. Defective microphone.
- 2. Defective microphone connector.
- 3. Inoperative microphone amplifier, (both AM and SSB modes.)

#### NO NOISE BLANKER OPERATION

With NB Switch ON, apply a 27 MHz carrier signal to antenna. Then check DC voltage at TP-1 varying the carrier signal from  $1 \mu V$  to  $100 \mu V$ .

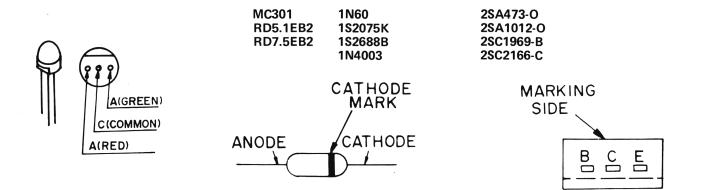
- 1. When TR1 voltage stays on and does not vary: Check TR1,2,3,4,5, D1 and D2.
- 2. When TP1 voltage varies from 0V to approx. 2V. Check TR6, 7 and 8.
- 3. If (A) and (B) are alright, L1 and/or L2 may be misaligned; go to alignment procedure for adjusting L1 and L2.

### CHANNEL LED DOES NOT LIGHT

When a specific segment fails to light, it is probable there is an open-circuit in the LED display or bad contact in the channel selector switch.

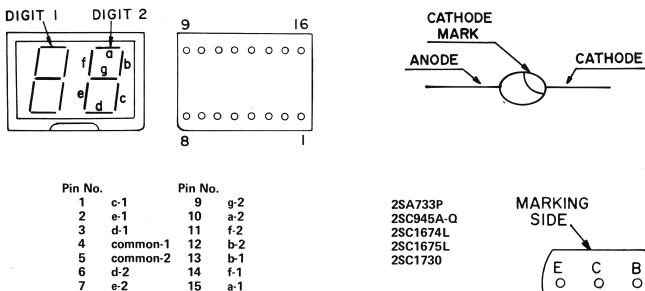
### **10. SEMICONDUCTOR PIN CONNECTIONS**

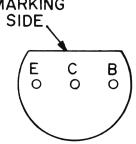
### **TLRG 101**



**UR-202** 

**KB-262** 





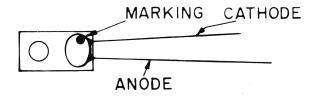
#### **MV-1Y**

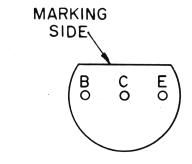
8

c-2

16

g-1

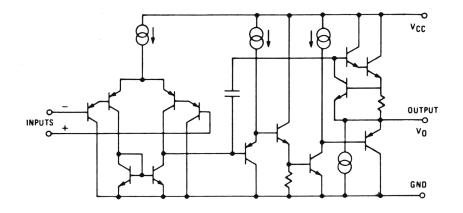


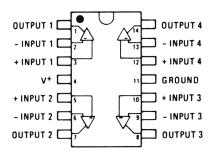


2SB525-C 2SC2086-D

## **11. IC INTERNAL DIAGRAMS**

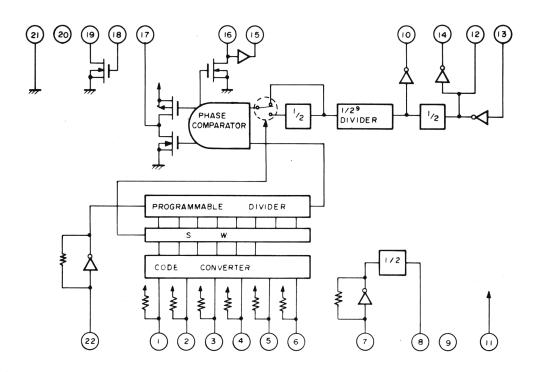
### IC1. TA75902P

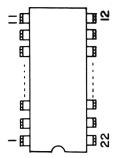




(Top View)

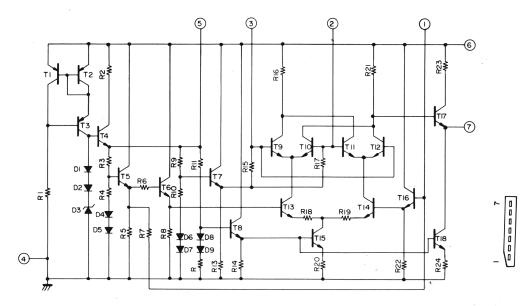
### **IC2.** μ**PD2824C**



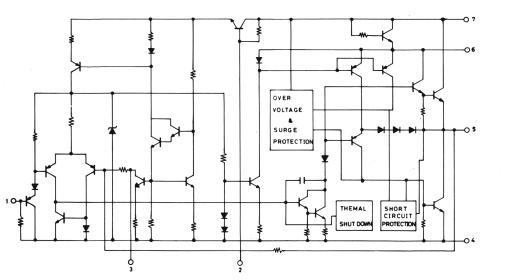


- 21 -

IC3. AN612

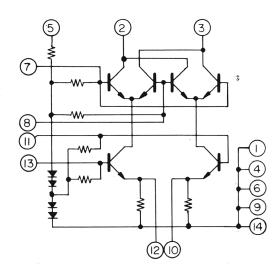


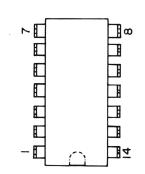
**IC4.** μ**PC1182H** 



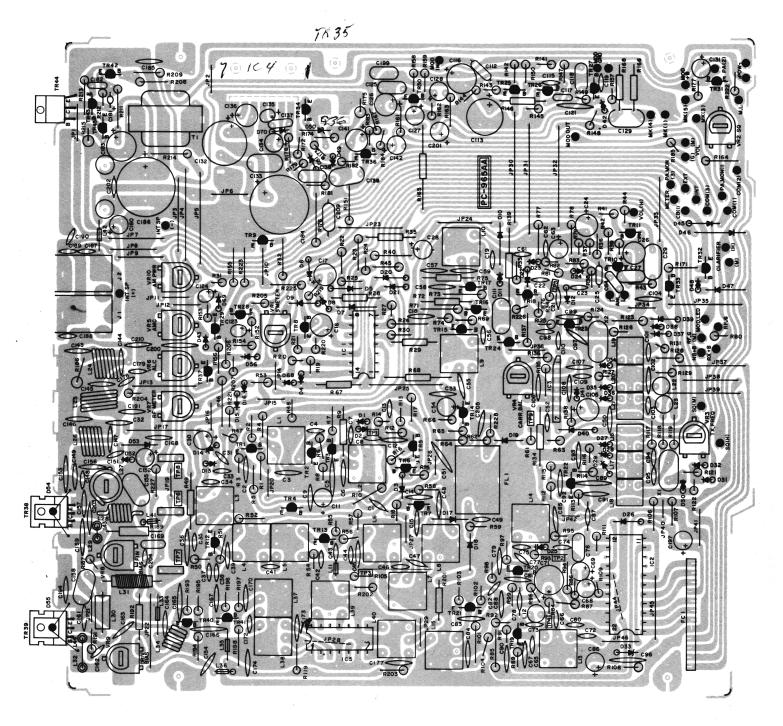


IC5. SO42P

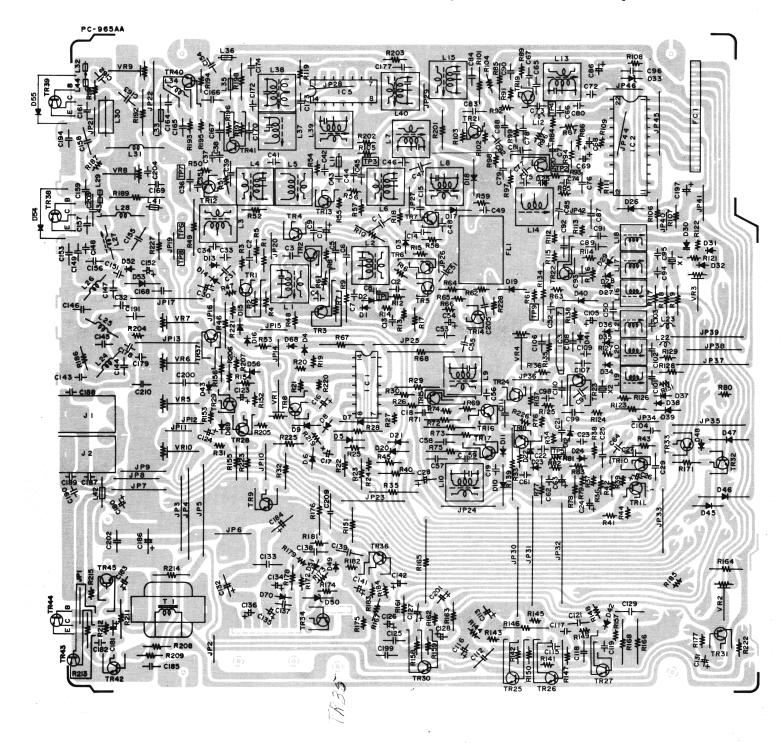




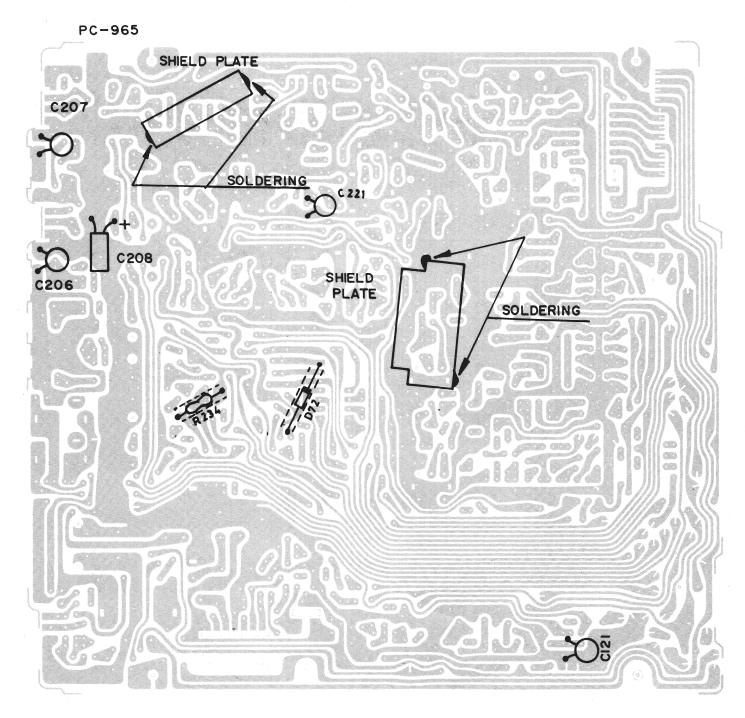
# 12. MAIN P.C. BOARD (TOP VIEW)



# 13. MAIN P.C. BOARD (BOTTOM VIEW)

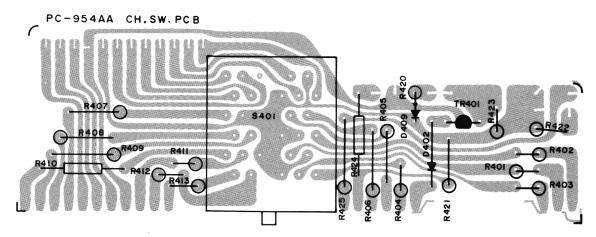


## 14. ADDITIONAL PARTS ON THE P.C. BOARD BOTTOM

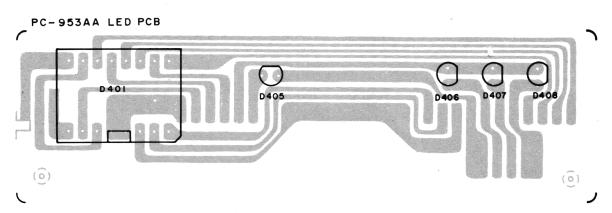


## 15. OTHER P.C. BOARDS

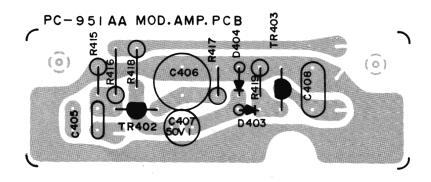
### CH. SW. P.C.B.



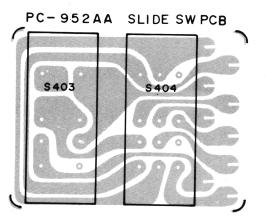
### LED P.C.B.



MOD. AMP. P.C.B.

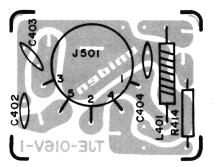


SLIDE SW P.C.B.

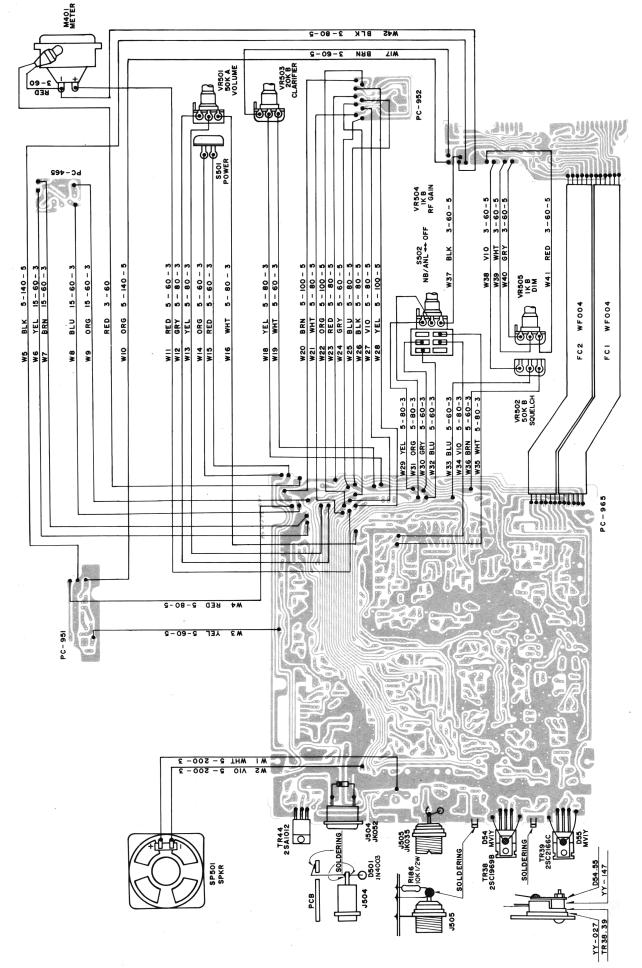


MIC P.C.B.

PC-465AA MIC PCB



### **16. WIRING DIAGRAM**



### **17. ELECTRICAL PARTS LIST**

The first code indicates tolerance of capacitors;  $C = \pm 0.25 pF$ ,  $D = \pm 0.5 pF$ ,  $F = \pm 1 pF$ ,  $G = \pm 2\%$ ,  $J = \pm 5\%$ ,  $K = \pm 10\%$ ,  $M = \pm 20\%$ , Z = +80% - 20%

The second code indicates variation of capacitance against temperature;  $YA = \pm 5\%$ ,  $YB = \pm 10\%$ , YD = +20 - 30%, YE = +20 - 50%, YF = +30 - 80%,  $(-25 \sim +85^{\circ}C)$ , ZF = +30 - 80%  $(-10 \sim +70^{\circ}C)$ ,  $CH = 0\pm 60$  ppm/°C, RH = -220 ppm/°C $\pm 60$  ppm/°C, TH = -4700 ppm/°C $\pm 60$  ppm/°C, SL = +350 ppm°/C  $\sim -1000$  ppm/°C, UJ = -750 ppm°/C $\pm 120$  ppm/°C

REF. NO.	DE	SCRIPTION		RS. PART NO.	MFRS PART NO.
CAPACITOF	RS				
C-1 C-2 C-3 C-4 C-5	Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic	10 pF 0.01 μF 0.01 μF 100 pF 0.047 μF	50V K SL 50V Z YF 50V Z YF 50V K SL 50V Z ZF		CCGZ 811025 CKGZ 811030 CKGZ 811030 CCGZ 811015 CKCZ 814730
C-6 C-7 C-8 C-9 C-10	Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic		50V Z YF 50V Z YF 50V K SL 50V Z YF used –		CKGZ 811030 CKGZ 811020 CKGZ 818205 CKGZ 811030
C-11 C-12 C-13 C-14 C-15 C-16	Capacitor, Electrolytic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Electrolytic	0.47 μF 330 pF 0.001 μF 330 pF 0.01 μF 47 μF	50V 50V K SL 50V Z YF 50V K SL 50V Z YF 10V		CELZ 814700 CCGZ 813315 CKGZ 811020 CCGZ 813315 CKGZ 811030 CELZ 114700
C-17 C-18 C-19 C-20 C-21	Capacitor, Electrolytic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic	18 pF	10V 50V Z YF 50V K SL used – 50V K SL	•	CELZ 114700 CKGZ 811030 CCGZ 811505 CCGZ 811805
C-22 C-23 C-24 C-25 C-26 C-27	Capacitor, Ceramic Capacitor, Ceramic Capacitor, Electrolytic Capacitor, Mylar Capacitor, Electrolytic Capacitor, Mylar	5 pF 15 pF 47 μF 0.001 μF 47 μF 0.047 μF	50V C SL 50V K SL 10V 50V K 10V 50V K		CCGZ 815091 CCGZ 811505 CELZ 114700 CQMZ811025 CELZ 114700 CQMZ814735
C-28 C-29 C-30 C-31 C-32 C-33	Capacitor, Electrolytic Capacitor, Mylar Capacitor, Electrolytic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic	22 μF 0.1 μF 10 μF 0.0047 μF 18 pF 0.0047 μF	10V 50V K 16V 50V Z YF 50V Z RH 50V Z YF		CELZ 112200 CQMZ811045 CELZ 311000 CKGZ 814720 CCRZ 811805 CKGZ 814720
C-34 C-35 C-36 C-37 C-38 C-39	Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic	0.0047 μF 0.001 μF 0.047 μF 10 pF 0.001 μF 0.01 μF	50V Z YF 50V Z YF 50V Z ZF 50V K SL 50V Z YF 50V Z YF		CKGZ 814720 CKGZ 811020 CKCZ 814730 CCGZ 811005 CKGZ 811020 CKGZ 811030
C-40 C-41 C-42 C-43 C-44 C-45	Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic		used – 50V C SL 50V Z YF 50V Z YF 50V Z YF 50V Z YF		CCGZ 812091 CKGZ 811020 CKGZ 811020 CKGZ 811020 CKGZ 811020 CKGZ 811030

REF. NO.	DES	CRIPTION	RS. PART NO.	MFRS PART NO.
C-46 C-47 C-48 C-50 C-51 C-52 C-53 C-55 C-55 C-55 C-56 C-57 C-58 C-59	Capacitor, Ceramic Capacitor, Ceramic	$\begin{array}{cccccccccccccccccccccccccccccccccccc$		CCGZ 812091 CCGZ 812091 CKGZ 911030 CCGZ 815091 CKGZ 811030 CKCZ 814730 CKGZ 811020 CKGZ 811030 CELZ 814730 CKCZ 814730 CCGZ 813305 CKCZ 814730 CKCZ 814730 CKCZ 814730
C-60 C-61 C-62 C-63 C-64 C-65 C-66 C-67 C-68 C-69 C-70 C-71	Capacitor, Ceramic Capacitor, Ceramic Capacitor, Electrolytic Capacitor, Mylar Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Electrolytic Capacitor, Electrolytic Capacitor, Electrolytic	- Not used - 10 pF 50V K SL 47 pF 50V K SL 1 $\mu$ F 50V K SL 27 pF 50V K SL 56 pF 50V K SL 0.01 $\mu$ F 50V K SL 0.01 $\mu$ F 50V Z YF 2.2 $\mu$ F 25V 2.2 $\mu$ F 25V - Not used - 100 $\mu$ F 10V		CCGZ 811005 CCGZ 814705 CELZ 811090 CQMZ 811035 CCGZ 812705 CCGZ 815605 CKGZ 811030 CELZ 512290 CELZ 512290 CELZ 111010
C-72 C-73 C-74 C-75 C-76 C-77 C-78 C-79 C-80 C-81 C-82 C-83 C-83 C-83 C-84 C-85 C-86 C-87	Capacitor, Electrolytic Capacitor, Ceramic Capacitor, Ceramic	$\begin{array}{cccccccccccccccccccccccccccccccccccc$		CCGZ 812091 CCGZ 812091 CKGZ 815091 CKGZ 811020 CCUZ 814705 CQMZ 814735 CCCZ 813305 CCGZ 811005 CCGZ 812715 CKGZ 811020 CCGZ 813915 CCGZ 811030 CKGZ 811030 CKGZ 811030 CKGZ 811030 CKGZ 811030
C-88 C-89 C-90 C-91 C-92 C-93 C-94 C-95 C-96 C-97 C-98 C-99 C-100 C-101 C-102 C-103	Capacitor, Ceramic Capacitor, Ceramic	0.047 $\mu$ F 50V Z ZF 0.047 $\mu$ F 50V Z ZF 0.01 $\mu$ F 50V Z YF 120 pF 50V K SL 290 pF 50V K SL 0.01 $\mu$ F 50V Z YF 0.001 $\mu$ F 50V Z YF 0.001 $\mu$ F 50V Z YF 0.001 $\mu$ F 50V Z YF 0.047 $\mu$ F 50V Z YF 100 pF 50V K SL 270 pF 50V K SL 270 pF 50V K SL - Not used - 22 pF 50V K CH 82 pF 50V K RH 15 pF 50V K RH		CKCZ 814730 CKCZ 814730 CKCZ 814730 CKGZ 811030 CCGZ 811215 CCGZ 813915 CKGZ 811030 CKGZ 811020 CKGZ 811020 CKGZ 811030 CKGZ 814730 CKGZ 814730 CKGZ 814730 CCGZ 812715 CCCZ 812205 CCRZ 818205 CCRZ 811505

REF. NO.	DES	SCRIPTION	RS. PART NO.	MFRS PART NO.
C-104	Capacitor, Ceramic	0.01 μF 50V Z YF		CKGZ 811030
C-105	Capacitor, Electrolytic	$100 \mu\text{F}$ 10V		CELZ 111010
C-106	Capacitor, Ceramic	0.01 µF 50V Z YF		CKGZ 811030
C-107	Capacitor, Ceramic	$0.01 \mu\text{F}$ 50V Z YF		CKGZ 811030
C-108	Capacitor, Ceramic	150 pF 50V K SL		CCGZ 811515
C-109	Capacitor, Ceramic	47 pF 50V K SL		CCGZ 814705
C-110	Capacitor, Ceramic	10 pF 50V K SL		CCGZ 811005
C-111	Capacitor, Mylar	0.1 µF 50V K		CQMZ 811045
C-112	Capacitor, Mylar	0.01 µF 50V K		CQMZ 811035
C-113	Capacitor, Electrolytic	220 µF 6.3V		CELZ 902210
C-114		– Not used –	·	
C-115	Capacitor, Ceramic	330 pF 50V K SL		CCGZ 813315
C-116	Capacitor, Electrolytic	100 μF 10V		CELZ 111010
C-117	Capacitor, Mylar	0.0047 μF 50V K		COMZ 814725
C-118	Capacitor, Mylar	0.047 μF 50V K		COMZ 814735
C-119	Capacitor, Ceramic	0.001 μF 50V Z YF		CKGZ 811020
C-120		– Not used –	à	01/07 0/1700
C-121	Capacitor, Ceramic	0.047 μF 50V Z ZF		CKCZ 814730
C-122		- Not used -		0057 00000
C-123	Capacitor, Tantalum	22 $\mu$ F 6.3V M		CSEZ 902206
C-124	Capacitor, Tantalum	2.2 μF 25V M		CSEZ 512296
C-125	Capacitor, Mylar	$0.047 \ \mu F = 50V \ K$		COMZ 814735
C-126	Capacitor, Electrolytic	47 μF 10V 0.47 μF 50V		CELZ 114700
C-127 C-128	Capacitor, Electrolytic Capacitor, Electrolytic			CELZ 814700 CELZ 811090
C-128 C-129	Capacitor, Electrolytic Capacitor, Myalr	1 μF 50V 0.1 μF 50V K		CQMZ811045
C-130	Capacitor, wryan	- Not used $-$		001012011045
C-131	Capacitor, Electrolytic	$4.7 \mu\text{F}$ 25V		CELZ 514790
C-132	Capacitor, Electrolytic	$330 \mu\text{F}$ 16V		CELZ 313310
C-133	Capacitor, Mylar	$0.1 \mu\text{F}$ 50V K		COMZ811045
C-134	Capacitor, Electrolytic	4.7 µF 25V		CELZ 514790
C-135	Capacitor, Tantalum	10 µF 10∨ M		CSEZ 111006
C-136	Capacitor, Electrolytic	.47 μF 10V		CELZ 114700
C-137	Capacitor, Mylar	0.01 µF 50V K		CQMZ811035
C-138	Capacitor, Mylar	0.047 µF 50V K		CQMZ814735
C-139	Capacitor, Mylar	0.068 μF 50V K		CQMZ816835
C-140		— Not used —		
C-141	Capacitor, Electrolytic	47 μF 10V		CELZ 114700
C-142	Capacitor, Electrolytic	1 μF 50V		CELZ 811090
C-143	Capacitor, Ceramic	82 $\mu$ F 50V K SL		CCGZ 818205
C-144	Capacitor, Ceramic	39 pF 50V K SL		CCGZ 813905
C-145	Capacitor, Ceramic	180 pF 50V K SL		CCGZ 811815 CCGZ 811815
C-146	Capacitor, Ceramic	180 pF 50V K SL		CCGZ 813905
C-147	Capacitor, Ceramic	39 pF 50V K SL		CCGZ 813905
C-148	Capacitor, Ceramic	47 pF 50V K SL 390 pF 50V K SL		CCGZ 813915
C-149 C-150	Capacitor, Ceramic	390 pF 50V K SL — Not used —		
C-150	Capacitor, Ceramic	1 pF 50V C SL		CCGZ 811091
C-152	Capacitor, Electrolytic	1μF 50V C 5L	х.	CELZ 811090
C-153	Capacitor, Ceramic	$0.047 \mu\text{F}$ 50V Z ZF		CKCZ 814730
C-154	Capacitor, Ceramic	$0.01 \mu\text{F}$ 50V Z YF		CKGZ 811030
C-155	Capacitor, Mylar	0.1 µF 50V K		COMZ811045
C-156	Capacitor, Ceramic	390 pF 50V K UJ		CCUZ 812215
C-157	Capacitor, Ceramic	220 pF 50V K UJ		CCUZ 811015
C-158	Capacitor, Mylar	0.1 µF 50V K		COMZ811045
C-159	Capacitor, Ceramic	470 pF 50V K SL		CCGZ 814715
C-160		- Not used -		00117 011015
C-161	Capacitor, Ceramic	100 pF 50V K UJ		CCUZ 811015

REF. NO.	DES	CRIPTION	RS PART NO.	MFRS PART NO.
C-162 C-163 C-164 C-165 C-166	Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic	$\begin{array}{rrrr} 0.001 \ \mu F & 50V \ Z & YF \\ 270 \ pF & 50V \ K & SL \\ 0.01 \ \mu F & 50V \ Z & YF \\ 0.01 \ \mu F & 50V \ Z & YF \\ 470 \ pF & 50V \ K & SL \\ \end{array}$		CKGZ 811020 CCGZ 812715 CKGZ 811030 CKGZ 811030 CCGZ 814715
C-167 C-168 C-169 C-170 C-171	Capacitor, Ceramic Capacitor, Ceramic Capacitor, Mylar Capacitor, Ceramic	$\begin{array}{rrrr} 0.0047 \ \mu F & 50V \ M \ YD \\ 0.01 \ \mu F & 50V \ Z \ YF \\ 0.01 \ \mu F & 50V \ K \\ 270 \ pF & 50V \ K \ SL \\ - \ Not \ used \ - \end{array}$		CKDZ 814726 CKGZ 811030 CQMZ 811035 CCGZ 812715
C-172 C-173 C-174 C-175 C-176	Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic	1 pF 50V C SL 0.01 μF 50V Z YF 0.01 μF 50V Z YF - Not used - - Not used -		CCGZ 811091 CKGZ 811030 CKGZ 811030
C-177 C-178 C-179 C-180 C-181 C-182 C-183 C-183 C-184	Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Electrolytic Capacitor, Tantalum Capacitor, Mylar Capacitor, Electrolytic Capacitor, Electrolytic	$\begin{array}{rrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrr$		CKGZ 811030 CCUZ 813092 CCCZ 812205 CELZ 811090 CSEZ 512246 CQMZ814725 CELZ 111010 CELZ 511020
C-185 C-186 C-187 C-188 C-189 C-190 C-191 C-191 C-192 C-193	Capacitor, Ceramic Capacitor, Electrolytic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic	$\begin{array}{rrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrr$		CKGZ 814720 CELZ 511020 CKGZ 811020 CKGZ 811020 CKGZ 811020 CKGZ 811020 CKGZ 811020
C-194 C-195 C-196	Capacitor, Ceramic	0.0047 μF 50V Z YF - Not used - - Not used -		CKGZ 814720
C-197 C-198 C-199 C-200 C-201 C-202 C-203 C-204 C-205 C-206 C-207 C-208 C-209 C-209 C-210 C-221 C-221 C-401	Capacitor, Electrolytic Capacitor, Ceramic Capacitor, Mylar Capacitor, Ceramic Capacitor, Electrolytic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Electrolytic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic	4.7 $\mu$ F 25V 0.0047 $\mu$ F 50V M YD 0.047 $\mu$ F 50V Z ZF 1 $\mu$ F 50V Z ZF 1 $\mu$ F 50V Z YF 0.001 $\mu$ F 50V Z YF 0.001 $\mu$ F 50V Z YF 0.001 $\mu$ F 50V Z YF 150 pF 50V Z YF 180 pF 50V Z YF 180 pF 50V Z YF 180 pF 50V Z YF 180 pF 50V Z YF 1 $\mu$ F 50V Z YF 1 $\mu$ F 50V Z YF 0.0047 $\mu$ F 50V Z YF 15 pF 50V SL - Not used -		CELZ 514790 CKDZ 814726 COMZ814735 CKCZ 814730 CELZ 811090 CKGZ 811020 CKGZ 814720 CKGZ 811020 CKGZ 811020 CKGZ 811526 CKGZ 811526 CELZ 811090 CKGZ 814735 CKGZ 814720 CCCZ 811505
C-402 C-403 C-404 C-405 C-406 C-407 C-408	Capacitor, Ceramic Capacitor, Ceramic Capacitor, Ceramic Capacitor, Mylar Capacitor, Electrolytic Capacitor, Electrolytic Capacitor, Mylar	$\begin{array}{rrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrrr$		CKGZ 811020 CKGZ 811020 CKGZ 814720 CQMZ 816825 CELZ 111010 CELZ 811090 CQMZ 813335

REF. NO.	DESCRIPTION	RS. PART NO.	MFRS PART NO.
COILS			
L-1 L-2 L-3 L-4 L-5 L-6 L-7 L-8 L-9 L-10 L-11 L-12 L-13 L-14 L-15 L-16 L-17 L-18 L-17 L-18 L-20 L-21 L-22 L-23 L-24 L-25 L-26 L-27 L-28 L-20 L-27 L-28 L-29 L-20 L-27 L-28 L-29 L-30 L-31 L-32 L-33 L-34 L-35 L-36 L-37 L-38 L-37 L-38 L-39 L-40 L-41 L-42 L-43 L-244 L-40 L-40	Coil         LA-120           Coil         LA-277           Coil         LA-279           Coil         LA-260           Coil         LA-259           Coil         LA-350           Coil         LA-350           Coil         LA-350           Coil         LA-350           Coil         LA-350           Coil         LA-351           Coil         LA-351           Coil         LA-166           Coil         LA-165           Coil         LA-165           Coil         LA-165           Coil         LB-137           Coil         LB-137           Coil         LB-137           Coil         LB-137           Coil         LB-137           Coil         LB-137           Coil         LZ-016           Coil         LZ-016           Coil         LZ-016           Coil         LZ-016           Coil         LE-088           Coil         LE-087           Coil         LE-087           Coil         LD-087           Coil         LD-087           Coil <td>۲H</td> <td>LLAY 120001 LLAY 277001 LLAY 279001 LLAY 260001 LLAY 259001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 351001 LLAY 351001 LLAY 166001 LLAY 166001 LLAY 166001 LLAY 166001 LLAY 166001 LLBY 137001 LLBY 137001 LLBY 137001 LLBY 137001 LLBY 137001 LLBY 137001 LLBY 089001 LLEY 088001 LLEY 088001 LLEY 088001 LLEY 088001 LLEY 08001 LLEY 187001 LLEY 187001 LLEY 187001 LLEY 187001 LLDY 087001 LLDY 087001 LLDY 087001 LLDY 087001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 350001 LLDY 087001 LLDY 087001 R</td>	۲H	LLAY 120001 LLAY 277001 LLAY 279001 LLAY 260001 LLAY 259001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 351001 LLAY 351001 LLAY 166001 LLAY 166001 LLAY 166001 LLAY 166001 LLAY 166001 LLBY 137001 LLBY 137001 LLBY 137001 LLBY 137001 LLBY 137001 LLBY 137001 LLBY 089001 LLEY 088001 LLEY 088001 LLEY 088001 LLEY 088001 LLEY 08001 LLEY 187001 LLEY 187001 LLEY 187001 LLEY 187001 LLDY 087001 LLDY 087001 LLDY 087001 LLDY 087001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 350001 LLAY 350001 LLDY 087001 LLDY 087001 R
CRYSTALS	Crystal QX-122 10.2417 MHz		QQXY122001
X-2	Crystal QX-122 10.2417 MHz Crystal QX-122 10.6975 MHz		QQXY122001 QQXY122002
DIODES		1	
D-1 D-2 D-3	Diode 1N60AM Diode 1N60AM Diode 1S2075K		DDAY001001 DDAY001001 DDAY063001

D-4         Diode         1S2075K           D-5         Diode         1N60AM           D-6         Diode         1S2075K           D-7         Diode         1S2075K           D-8         Diode         1S2075K           D-9         Diode         1S2075K           D-10         Diode         1S2075K	DDAY063001 DDAY001001
D-5         Diode         1N60AM           D-6         Diode         1S2075K           D-7         Diode         1S2075K           D-8         Diode         1S2075K           D-9         Diode         1S2075K	
D-6         Diode         1S2075K           D-7         Diode         1S2075K           D-8         Diode         1S2075K           D-9         Diode         1S2075K	
D-7         Diode         1S2075K           D-8         Diode         1S2075K           D-9         Diode         1S2075K	DDAY063001
D-8 Diode 1S2075K D-9 Diode 1S2075K	DDAY 063001
D-9 Diode 1S2075K	DDAY 063001
	DDAY 063001
	DDAY001001
D-11 Diode 1N60AM	DDAY001001
D-12 Diode 1S2075K	DDAY 063001
D-13 Diode MC301	DDAY090001
D-14 Diode MC301	DDAY 090001
D-15 Diode 1S2075K	DDAY063001
D-16 Diode 1S2075K	DDAY063001
D-17 Diode 1S2075K	DDAY063001
D-18 Diode 1S2075K	DDAY063001
D-19 Diode 1S2075K	DDAY063001
D-20 Diode 1S2075K	DDAY063001
D-21 Diode 1S2075K	DDAY063001
D-22 Diode 1S2075K	DDAY063001
D-23 Diode 1S2075K	DDAY063001
D-24 Diode 1S2075K	DDAY063001
D-25 Diode 1S2688EB	DDAY006009
D-26 Diode 1S2075K	DDAY063001
D-27 Diode 1S2075K	DDAY063001
D-28 Diode 1S2075K	DDAY063001
D-29 Diode 1S2075K	DDAY063001
D-30 Diode 1S2688EB D-31 Diode 1S2075K	DDAY006009
D-31 Diode 1S2075K D-32 Diode 1S2075K	DDAY063001
D-32 Diode RD5.1EB2	DDAY063001
D-34 Diode 1S2075K	DDAY086014 DDAY063001
D-35 Diode 1S2075K	DDAY063001
D-36 Diode 1S2075K	DDAY063001
D-37 Diode 1S2075K	DDAY063001
D-38 Diode 1S2075K	DDAY063001
D-39 Diode 1S2075K	DDAY063001
D-40 Diode 1S2075K	DDAY063001
D-41 Diode 1S2075K	DDAY063001
D-42 Diode 1S2075K	DDAY063001
D-43 Diode 1S2075K	DDAY063001
D-44 — Not used —	
D-45 Diode 1S2075K	DDAY063001
D-46 Diode 1S2075K	 DDAY063001
D-47 Diode 1S2075K	DDAY063001
D-48 Diode 1S2075K	DDAY063001
D-49 Varistor, Diode KB262	DDFY 004002
D-50 Zener, Diode, RD7.5EB2	DDAY086009
D-51 Diode 1S2075K	DDAY063001
D-52 Diode 1S2075K D-53 Diode 1S2075K	DDAY063001
	DDAY063001
D-54 Varistor, Diode MV-1Y D-55 Varistor, Diode MV-1Y	DDFY 020001
D-55 Varistor, Diode MV-TY D-56 Diode 1S2075K	DDFY 020001
D-56 - Not used -	DDAY063001
D-68 Diode 1S2075K	DDAY063001
D-69 Diode 1N60AM	DDAY001001
D-70 Diode 1S2075K	DDAY063001
D-72 Diode, Zener RD5.1EB2	DDAY086014
D-401 Diode, LED UR-202	DDAY 113001

REF. NO.	D	ESCRIPTION		RS. PART NO.	MFRS PART NO.
D-402 D-403 D-404 D-405 D-406 D-407 D-408 D-409 D-501	Diode Diode Diode, LED Diode, LED Diode, LED Diode, LED Diode Diode	1S2075K 1N60AM 1N60AM TLR-124 TLR-124 TLR-124 TLR-124 1S2075K 1N4003		DX-1118	DDAY 063001 DDAY 001001 DDAY 001001 DDAY 100001 DDAY 100001 DDAY 100001 DDAY 100001 DDAY 063001 DDAY 133001
INTEGRATE					
IC-1 IC-2 IC-3 IC-4 IC-5	Integrated Circuit Integrated Circuit Integrated Circuit Integrated Circuit Integrated Circuit Tolerance Code	TA-75902P $\mu$ PD2824C AN612 $\mu$ PC1182H SO42P J = 5%	LINEAR DIGITAL LINEAR LINEAR LINEAR		DDEY 284001 DDEY 190001 DDEY 130001 DDEY 149001 DDEY 132001
RESISTORS		<b>K</b> = 10%		1	
R-1 R-2 R-3 R-4 R-5 R-6 R-7 R-8 R-9 R-10 R-12 R-13 R-12 R-13 R-14 R-15 R-16 R-17 R-15 R-16 R-17 R-20 R-21 R-22 R-21 R-22 R-23 R-24 R-25 R-25 R-26 R-27 R-28 R-20 R-27 R-28 R-20 R-27 R-28 R-20 R-27 R-20 R-27 R-28 R-20 R-27 R-28 R-20 R-27 R-28 R-20 R-27 R-28 R-20 R-27 R-28 R-20 R-27 R-28 R-20 R-27 R-28 R-37 R-38 R-39 R-37 R-38 R-37 R-37 R-37 R-37 R-37 R-37 R-37 R-37	Resistor, Carbon Film Resistor, Carbon Film	33K ohm 680 ohm 220 ohm 330 ohm 47K ohm 2.7K ohm 330 ohm 68 ohm 10K ohm 10K ohm 10K ohm 330 ohm 3.3K ohm 10K ohm 33K ohm 100K ohm	1/8W J 1/8W J		RUBZ 181034 RUBZ 183334 RUBZ 186814 RUBZ 182214 RUBZ 182214 RUBZ 183314 RUBZ 184734 RUBZ 181034 RUBZ 181034 RUBZ 181034 RUBZ 181034 RUBZ 181034 RUBZ 181034 RUBZ 181034 RUBZ 183314 RUBZ 183324 RUBZ 183934 RUBZ 183934 RUBZ 183934 RUBZ 184754 RUBZ 184754 RUBZ 181044 RUBZ 181034 RUBZ 181034

REF. NO.	DE	SCRIPTION		· · ·	RS. PART NO.	MFRS PART NO.
R-41	Resistor, Carbon Film	470 ohm	1/8W	J		RUBZ 184714
R-42	Resistor, Carbon Film	3.3K ohm	1/8W	J		RUBZ 183324
R-43	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ 181034
R-44	Resistor, Carbon Film	5.6K ohm	1/8W	J		RUBZ 185624
R-45	Resistor, Carbon Film	15K ohm	1/8W	J		RUBZ 181534
R-46	Resistor, Carbon Film	8.2K ohm	1/8W	J		RUBZ 188224
R-47 R-48	Resistor, Carbon Film	2.2K ohm	1/8W	J		RUBZ 182224
R-40	Resistor, Carbon Film Resistor, Carbon Film	1K ohm 1K ohm	1/8W 1/8W	J J		RUBZ 181024 RPBZ 181024
R-50	Resistor, Carbon Film	1K ohm	1/8W	J		RUBZ 181024
R-51	Resistor, Carbon Film	2.2K ohm	1/8W	J		RUBZ 182224
R-52	Resistor, Carbon Film	100 ohm	1/8W	J		RUBZ 181014
R-53	Resistor, Carbon Film	470 ohm	1/8W	J		RUBZ 184714
R-54	Resistor, Carbon Film	100 ohm	1/8W	J		RUBZ 181014
R-55	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ 181034
R-56	Resistor, Carbon Film	82K ohm	1/8W	J		RUBZ 188234
R-57	Resistor, Carbon Film	100 ohm	1/8W	J		RUBZ181014
R-58	Resistor, Carbon Film	470 ohm	1/8W	J		RUBZ 184714
R-59	Resistor, Carobn Film	10K ohm	1/8W	J		RUBZ 181034
R-60 R-61	Bosistor Carbon Film		used –			
R-62	Resistor, Carbon Film Resistor, Carbon Film	1K ohm 1.1K ohm	1/8W 1/8W	J		RPBZ 181024
R-63	Resistor, Carbon Film	8.2K ohm	1/8W	J J		RUBZ 181224 RUBZ 188224
R-64	Resistor, Carbon Film	22K ohm	1/8W	J		RUBZ 182234
R-65	Resistor, Carbon Film	5.6K ohm	1/8W	J		RUBZ 182234
R-66	Resistor, Carbon Film	680 ohm	1/8W	J		RUBZ 186814
R-67	Resistor, Carbon Film	2.2K ohm	1/8W	J		RPBZ 182224
R-68	Resistor, Carbon Film	100 ohm	1/8W	J		RPBZ 181014
R-69	Resistor, Carbon Film	47K ohm	1/8W	J		RUBZ184734
R-70			used –			
R-71	Resistor, Carbon Film	1.5K ohm	1/8W	J		RUBZ181524
R-72 R-73	Resistor, Carbon Film	100 ohm	1/8W	J		RPBZ 181014
R-73	Resistor, Carbon Film Resistor, Carbon Film	270 ohm 150 ohm	1/8W 1/8W	J		RUBZ182714
R-75	Resistor, Carbon Film	68 ohm	1/8W	J		RUBZ181514
R-76	Resistor, Carbon Film	3.3K ohm	1/8W	J		RUBZ186804 RUBZ183324
R-77	Resistor, Carbon Film	1.5M ohm	1/8W	J		RUBZ181554
R-78	Resistor, Carbon Film	220K ohm	1/8W	J		RUBZ182244
R-79	Resistor, Carbon Film	47K ohm	1/8W	J		RUBZ184734
R-80	Resistor, Carbon Film	1.5K ohm	1/8W	J		RUBZ181524
R-81	Resistor, Carbon Film	47K ohm	1/8W	J		RUBZ184734
R-82	Resistor, Carbon Film	100K ohm	1/8W	J		RUBZ181044
R-83	Resistor, Carbon Film	100K ohm	1/8W	J		RUBZ181044
R-84 R-85	Resistor, Carbon Film	3.3K ohm	1/8W	J		RPBZ 183324
R-86	Resistor, Carbon Film	15 ohm	1/8W	J		RUBZ181504
R-87	Resistor, Carbon Film Resistor, Carbon Film	5.6K ohm 470 ohm	1/8W 1/8W	J		RUBZ185624
R-89	Resistor, Carbon Film	1K ohm	1/8W	J		RUBZ184714 RUBZ181024
R-91	Resistor, Carbon Film	2.2K ohm	1/8W	J.		RUBZ 181024 RUBZ 182224
R-92	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ182224
R-93	Resistor, Carbon Film	22K ohm	1/8W	J		RPBZ 182234
R-94	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ181034
R-95	Resistor, Carbon Film	1K ohm	1/8W	J		RUBZ181024
R-96	Resistor, Carbon Film	15K ohm	1/8W	J		RUBZ181534
R-97	Resistor, Carbon Film	6.8K ohm	1/8W	J		RUBZ186824
R-98	Resistor, Carbon Film	330 ohm	1/8W	J		RUBZ183314
R-99 R-101	Resistor, Carbon Film	56 ohm	1/8W	J		RUBZ185604
	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ181034

REF. NO.	DE	SCRIPTION			RS. PART NO.	MFRS PART NO.
R-102	Resistor, Carbon Film	4.7K ohm	1/8W	J		RUBZ 184724
R-103	Resistor, Carbon Film	1K ohm	1/8W	J		RUBZ 181024
R-104	Resistor, Carbon Film	100 ohm	1/8W	J		RUBZ 181014
R-105	Resistor, Carbon Film	56 ohm	1/8W	J		RPBZ 185604
R-106	Resistor, Carbon Film	100 ohm	1/8W	J		RUBZ 181014
R-107	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ 181034
R-108	Resistor, Carbon Film	22K ohm	1/8W	J		RUBZ 182234
R-109	Resistor, Carbon Film	1.5K ohm	1/8W	J		RUBZ 181524
R-111	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ 181034
R-112	Resistor, Carbon Film	470 ohm	1/8W	J		RUBZ 184714
R-113 R-114	Resistor, Carbon Film Resistor, Carbon Film	680 ohm 22K ohm	1/8W 1/8W	J		RUBZ 186814 RUBZ 182234
R-115	Resistor, Carbon Film	22K ohm	1/8W	J		RUBZ 182234
R-116	Resistor, Carbon Film	1.8K ohm	1/8W	J		RUBZ 181824
R-117	Resistor, Carbon Film	4.7K ohm	1/8W	J		RUBZ 184724
R-118	Resistor, Carbon Film	4.7K ohm	1/8W	J		RUBZ 184724
R-119	Resistor, Carbon Film	4.7K ohm	1/8W	Ĵ	à	RUBZ 184724
R-121	Resistor, Carbon Film	100K ohm	1/8W	J		RUBZ 181044
R-122	Resistor, Carbon Film	15K ohm	1/8W	J		RUBZ 181534
R-123	Resistor, Carbon Film	220 ohm	1/8W	J		RUBZ 182214
R-124	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ 181034
R-125	Resistor, Carbon Film	1K ohm	1/8W	J		RUBZ181024
R-126	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ181034
R-127	Resistor, Carbon Film	2.2K ohm	1/8W	J		RUBZ 182224
R-128 R-129	Resistor, Carbon Film Resistor, Carbon Film	4.7K ohm 1.5K ohm	1/8W 1/8W	J		RUBZ 184724
R-131	Resistor, Carbon Film	1.5K ohm	1/8W	J		RUBZ 181524 RUBZ 181524
R-134	Resistor, Carbon Film	100 ohm	1/8W	J		RPBZ 181014
R-135	Resistor, Carbon Film	180K ohm	1/8W	J		RUBZ181844
R-136	Resistor, Carbon Film	270K ohm	1/8W	J		RUBZ 182744
R-137	Resistor, Carbon Film	3.3K ohm	1/8W	J		RUBZ183324
R-138	Resistor, Carbon Film	3.3K ohm	1/8W	J		RUBZ183324
R-139	Resistor, Carbon Film	5.6K ohm	1/8W	J		RPBZ 185624
R-141	Resistor, Carbon Film	220 ohm	1/8W	J		RUBZ182214
R-142	Resistor, Carbon Film	3.3K ohm	1/8W	J		RUBZ183324
R-143	Resistor, Carbon Film	10 ohm	1/8W	J		RUBZ181004
R-144	Resistor, Carbon Film	820 ohm	1/8W 1/8W	J		RUBZ188214
R-145 R-146	Resistor, Carbon Film Resistor, Carbon Film	270 ohm 100K ohm	1/8W	J		RUBZ182714 RPBZ 181044
R-140	Resistor, Carbon Film	4.7K ohm	1/8W	J		RUBZ184724
R-148	Resistor, Carbon Film	3.3K ohm	1/8W	J		RUBZ183324
R-149	Resistor, Carbon Film	390 ohm	1/8W	J		RUBZ183914
R-150	Resistor, Carbon Film	15K ohm	1/8W	Ĵ		RUBZ181534
R-151	Resistor, Carbon Film	390 ohm	1/8W	J		RUBZ183914
R-152	Resistor, Carbon Film	470 ohm	1/8W	J		RUBZ184714
R-153	Resistor, Carbon Film	3.3K ohm	1/8W	J		RUBZ183324
R-154	Resistor, Carbon Film	22K ohm	1/8W	J		RUBZ182234
R-155	Resistor, Carbon Film	1.5K ohm	1/8W	J		RUBZ181524
R-156	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ181034
R-157	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ181034
R-158 R-159	Resistor, Carbon Film	2.2K ohm	1/8W 1/8W	J		RUBZ182224
R-161	Resistor, Carbon Film Resistor, Carbon Film	10K ohm 1K ohm	1/8W	J J		RPBZ 181034 RUBZ181024
R-162	Resistor, Carbon Film	4.7K ohm	1/8W	J		RUBZ181024
R-163	Resistor, Carbon Film	1.5K ohm	1/8W	J		RUBZ181524
R-164	Resistor, Carbon Film	10K ohm	1/8W	J		RUBZ181034
R-165	Resistor, Carbon Film	22K ohm	1/8W	J		RUBZ182234
R-167	Resistor, Carbon Film	3.3K ohm	1/8W	J		RUBZ183324

REF. NO.	DE	SCRIPTION	RS. PART NO.	MFRS PART NO.
R-168	Resistor, Carbon Film	10K ohm 1/8W J		RPBZ 181034
R-171	Resistor, Carbon Film	680 ohm 1/8W J		RUBZ 186814
R-172	Resistor, Carbon Film	47 ohm 1/8W J		RUBZ 184704
R-173	Resistor, Carbon Film	56 ohm 1/8W J		RUBZ 185604
R-174	Resistor, Carbon Film	1K ohm 1/8W J		RUBZ 181024
R-175	Resistor, Metal Film	100 ohm 1W K		RSJZ 101015
R-176	Resistor, Carbon Film	15K ohm 1/8W J		RUBZ 181534
R-177	Resistor, Carbon Film	1.5K ohm 1/8W J		RUBZ 181524
R-178	Resistor, Carbon Film	1.8K ohm 1/8W J		RUBZ 181824
R-179	Resistor, Carbon Film	10K ohm 1/8W J		RUBZ 181034
R-181	Resistor, Carbon Film	4.7K ohm 1/8W J		RUBZ 184724
R-182	Resistor, Carbon Film	220 ohm 1/8W J		RUBZ 182214
R-183	Resistor, Carbon Film	1K ohm 1/8W J		RUBZ181024
R-184	Resistor, Carbon Film	680K ohm 1/8W J		RUBZ186844
R-185	Resistor, Carbon Film	12K ohm 1/8W J		RUBZ 181234
R-186	Resistor, Carbon Film	10K ohm 1/2W J		RPBZ 121034
R-187	Resistor, Carbon Film	47 ohm 1/8W J		RUBZ 184704
R-189	Resistor, Carbon Film	150 ohm 1/2W J		RPBZ 121514
R-191	Resistor, Carbon Film	1K ohm 1/8W J		RUBZ 181024
R-192	Resistor, Carbon Film	330 ohm 1/8W J		RPBZ 183314
R-193	Resistor, Carbon Film	10 ohm 1/8W J		RUBZ181004
R-194	Resistor, Carbon Film	1.5K ohm 1/8W J		RUBZ181524
R-195	Resistor, Carbon Film	330 ohm 1/8W J		RUBZ183314
R-196	Resistor, Carbon Film	47 ohm 1/8W J		RUBZ184704
R-197	Resistor, Carbon Film	1K ohm 1/8W J		RUBZ181024
R-198	Resistor, Carbon Film	3.3K ohm 1/8W J		RUBZ183324
R-199	Resistor, Carbon Film	100 ohm 1/8W J		RUBZ181014
R-201	Resistor, Carbon Film	560 ohm 1/8W J		RPBZ 185614
R-202	Resistor, Carbon Film	330 ohm 1/8W J		RUBZ183314
R-203	Resistor, Carbon Film	470 ohm 1/8W J		RUBZ184714
R-204	Resistor, Carbon Film	470 ohm 1/8W J		RUBZ184714
R-205	Resistor, Carbon Film	1.5K ohm 1/8W J		RUBZ181524
R-206	Resistor, Carbon Film	470 ohm 1/8W J		RUBZ184714
R-207	Resistor, Carbon Film	18K ohm 1/8W J		RUBZ181034
R-208	Resistor, Carbon Film	3.3K ohm 1/8W J		RUBZ183324
R-209 R-211	Resistor, Carbon Film	5.6K ohm 1/8W J 8.2 ohm 1/8W J		RUBZ185624
R-212	Resistor, Carbon Film Resistor, Carbon Film			RUBZ188204
R-212	Resistor, Carbon Film	560 ohm 1/8W J 10K ohm 1/8W J		RUBZ185614 RUBZ181034
R-214	Resistor, Carbon Film	1K ohm 1/8W J		RUBZ181024
R-215	Resistor, Carbon Film	150 ohm 1/2W J		RPBZ 181514
R-219	Resistor, Carbon Film	3.9K ohm 1/8W J		RUBZ183924
R-220	Resistor, Carbon Film	1K ohm 1/8W J		RUBZ181024
R-221	Resistor, Carbon Film	1K ohm 1/8W J		RUBZ181024
R-222	Resistor, Carbon Film	47 ohm 1/8W J		RUBZ184704
R-223	Resistor, Carbon Film	180K ohm 1/8W J		RUBZ181844
R-225	Resistor, Carbon Film	10K ohm 1/8W J		RUBZ181034
R-226	Resistor, Carbon Film	1K ohm 1/8W J		RUBZ181024
R-228	Resistor, Carbon Film	1.2K ohm 1/8W J		RUBZ181224
R-229	Resistor, Carbon Film	1.2K ohm 1/8W J		RUBZ181224
R-230	Resistor, Carbon Film	1.2K ohm 1/8W J		RUBZ181224
R-234	Resistor, Carbon Film	4.7K ohm 1/8W J		RUBZ184724
R-401	Resistor, Carbon Film	330 ohm 1/8W J		RUBZ183314
R-402	Resistor, Carbon Film	680 ohm 1/8W J		RUBZ186814
R-403	Resistor, Carbon Film	680 ohm 1/8W J		RUBZ186814
R-404	Resistor, Carbon Film	680 ohm 1/8W J		RUBZ186814
R-405	Resistor, Carbon Film	680 ohm 1/8W J		RUBZ186814
R-406	Resistor, Carbon Film	680 ohm 1/8W J		RUBZ186814
			1	1

R-407Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-408Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-409Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-410Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-411Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-412Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-413Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-414Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-414Resistor, Carbon Film100 ohm1/8WJRUBZ 1863R-415Resistor, Carbon Film10K ohm1/8WJRUBZ 1810R-416Resistor, Carbon Film10K ohm1/8WJRUBZ 1843R-417Resistor, Carbon Film820 ohm1/8WJRUBZ 1863R-418Resistor, Carbon Film6.8K ohm1/8WJRUBZ 1863R-419Resistor, Carbon Film10K ohm1/8WJRUBZ 1810R-419Resistor, Carbon Film10K ohm1/8WJRUBZ 1861RUBZ 1810RUBZ 1861RUBZ 1861RUBZ 1861RUBZ 1861R-419Resistor, Carbon Film10K ohm1/8WJRUBZ 1810	814 814 814 814 814 814 814
R-409Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-410Resistor, Carbon Film680 ohm1/8WJRPBZ 1863R-411Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-412Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-413Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-414Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-414Resistor, Carbon Film100 ohm1/8WJRUBZ 1863R-415Resistor, Carbon Film100 ohm1/8WJRUBZ 1810R-416Resistor, Carbon Film10K ohm1/8WJRUBZ 1843R-417Resistor, Carbon Film820 ohm1/8WJRUBZ 1863R-418Resistor, Carbon Film6.8K ohm1/8WJRUBZ 1863	814 814 814 814 814 814
R-410Resistor, Carbon Film680 ohm1/8WJRPBZ 1863R-411Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-412Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-413Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-413Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-414Resistor, Carbon Film100 ohm1/8WJRUBZ 1810R-415Resistor, Carbon Film10K ohm1/8WJRUBZ 1810R-416Resistor, Carbon Film47K ohm1/8WJRUBZ 1843R-417Resistor, Carbon Film820 ohm1/8WJRUBZ 1883R-418Resistor, Carbon Film6.8K ohm1/8WJRUBZ 1863	814 814 814 814
R-411Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-412Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-413Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-414Resistor, Carbon Film100 ohm1/8WJRUBZ 1863R-415Resistor, Carbon Film100 ohm1/8WJRUBZ 1810R-416Resistor, Carbon Film10K ohm1/8WJRUBZ 1841R-417Resistor, Carbon Film820 ohm1/8WJRUBZ 1882R-418Resistor, Carbon Film6.8K ohm1/8WJRUBZ 1863	814 814 814
R-412Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-413Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-414Resistor, Carbon Film100 ohm1/8WJRPBZ 1810R-415Resistor, Carbon Film10K ohm1/8WJRUBZ 1863R-416Resistor, Carbon Film47K ohm1/8WJRUBZ 1841R-417Resistor, Carbon Film820 ohm1/8WJRUBZ 1882R-418Resistor, Carbon Film6.8K ohm1/8WJRUBZ 1863	814 814
R-413Resistor, Carbon Film680 ohm1/8WJRUBZ 1863R-414Resistor, Carbon Film100 ohm1/8WJRPBZ 1810R-415Resistor, Carbon Film10K ohm1/8WJRUBZ 1810R-416Resistor, Carbon Film47K ohm1/8WJRUBZ 1841R-417Resistor, Carbon Film820 ohm1/8WJRUBZ 1882R-418Resistor, Carbon Film6.8K ohm1/8WJRUBZ 1863	814
R-414Resistor, Carbon Film100 ohm1/8WJRPBZ 1810R-415Resistor, Carbon Film10K ohm1/8WJRUBZ 1810R-416Resistor, Carbon Film47K ohm1/8WJRUBZ 1840R-417Resistor, Carbon Film820 ohm1/8WJRUBZ 1880R-418Resistor, Carbon Film6.8K ohm1/8WJRUBZ 1860	
R-415Resistor, Carbon Film10K ohm1/8WJRUBZ 1810R-416Resistor, Carbon Film47K ohm1/8WJRUBZ 1847R-417Resistor, Carbon Film820 ohm1/8WJRUBZ 1882R-418Resistor, Carbon Film6.8K ohm1/8WJRUBZ 1865	014
R-416Resistor, Carbon Film47K ohm1/8WJRUBZ 184R-417Resistor, Carbon Film820 ohm1/8WJRUBZ 188R-418Resistor, Carbon Film6.8K ohm1/8WJRUBZ 1868	004
R-417Resistor, Carbon Film820 ohm1/8WJRUBZ 1883R-418Resistor, Carbon Film6.8K ohm1/8WJRUBZ 1863	
R-418 Resistor, Carbon Film 6.8K ohm 1/8W J RUBZ 1868	
R-421Resistor, Carbon Film2.2K ohm1/8WJRUBZ 1822R-422Resistor, Carbon Film3.9K ohm1/8WJRUBZ 1839	
R-424Resistor, Carbon Film820 ohm1/8WJRPBZ1882R-425Resistor, Carbon Film470 ohm1/8WJRUBZRUBZ1842	
SEMI-FIXED RESISTORS	/ 14
VR-1 Semi-fixed Resistor RV-182 5K ohm B RRVY 182	004
VR-1 Semi-fixed Resistor RV-162 SK ohm B RRVY182	
VR-3 Semi-fixed Resistor RV-182 50K ohm B RRVY182	
VR-4 Semi-fixed Resistor RV-182 10K ohm B RRVY 182	
VR-5 Semi-fixed Resistor RV-182 1K ohm B RRVY182	
VR-6 Semi-fixed Resistor RV-182 10K ohm B RRVY182	
VR-7 Semi-fixed Resistor RV-182 100K ohm B RRVY182	
VR-8 Semi-fixed Resistor RV-182 100 ohm B RRVY182	
VR-9 Semi-fixed Resistor RV-182 3K ohm B RRVY182	
VR-10 Semi-fixed Resistor RV-182 5K ohm B RRVY182	
SWITCHES	
S-401 Switch (Channel) SR-241 SSRY 241	
S-402 Switch (MODE) SR-312 SSRY 312	
S-403 Switch (EXT. SP/BOTH/INT SP) SW-252 SSWY 252	
S-404 Switch (PA/CB/MON) SW-253 SSWY 253	
S-501 Switch (POW. SW) WITH VR501 RRVY320	
S-502 Switch (NB/ANL) WITH VR504 RRVY353	8001
TRANSISTORS	
TR-1 Transistor 2SC1675-L DDBY 259	001
TR-2 Transistor 2SC1675-L DDBY 269	
TR-3 Transistor 2SC1730-L DDBY 269	
TR-4 Transistor 2SC945A-Q DDBY 224	
TR-5 Transistor 2SC945A-Q DDBY 224	
TR-6 Transistor 2SA733-P DDBY 003	
TR-7 Transistor 2SC945A-Q DDBY 224	
TR-8 Transistor 2SC945A-Q DDBY 224	
TR-9 Transistor 2SC945A-Q DDBY 224	003
TR-10 Transistor 2SC945A-Q DDBY 224	003
TR-11 Transistor 2SC945A-Q DDBY 224	
TR-12 Transistor 2SC1674-L DDBY 295	
TR-13 Transistor 2SC1675-L DDBY 259	
TR-14 Transistor 2SC1674-L DDBY 295	002

REF. NO.	DESCRI	PTION		RS. PART NO.	MFRS PART NO.
TR-15	Transistor 2SC1675-L				DDBY 259001
TR-16	Transistor 2SC1675-L				DDBY 259001
TR-17	Transistor 2SC1730-L				DDBY 269001
TR-18	Transistor 2SC945A-C	1			DDBY 224003
TR-19	Transistor 25C045A-C				DDBY 259001
TR-20	Transistor 2SC1075-L				DDBY 259001
TR-21					
	Transistor 2SC1675-L				DDBY 259001
TR-22	Transistor 2SC1675-L				DDBY 259001
TR-23	Transistor 2SC1675-L				DDBY 259001
TR-24	Transistor 2SC954A-C				DDBY 224003
TR-25	Transistor 2SC954A-C				DDBY 224003
TR-26	Transistor 2SC1312F				DDBY 317001
TR-27	Transistor 2SC945A-C	<u>l</u>			DDBY 224003
TR-28	Transistor 2SA733-P			•	DDBY 003001
TR-29	Transistor 2SC945A-C	<u>)</u>			DDBY 224003
TR-30	Tranaistor 2SC945A-C				DDBY 224003
TR-31	Transistor 2SB525-C				DDBY 106003
TR-32	Transistor 2SC945A-C	)			DDBY 224003
TR-33	Transistor 2SB525-C	•			DDBY 106003
TR-34	Transistor 250323-C				DDBY 224003
		-			
TR-35	Transistor 2SA473-0				DDBY 028001
TR-36	Transistor 2SC945A-C	1			DDBY 224003
TR-37	Transistor 2SC1675-L				DDBY 259001
TR-38	Transistor 2SC1969-B		•		DDBY 307001
TR-39	Transistor 2SC2166-C				DDBY 331002
TR-40	Transistor 2SC2086-D				DDBY 228002
TR-41	Transistor 2SC1730-L				DDBY 269001
TR-42	Transistor 2SC945A-C	<u>!</u>			DDBY 224003
TR-43	Transistor 2SB525-C				DDBY 106003
TR-44	Transistor 2SA1012-0				DDBY 029001
TR-45	Transistor 2SC945A-C	1			DDBY 224003
TR-401	Transistor 2SC945A-C				DDBY 224003
TR-402	Transistor 2SC945A-C				DDBY 224003
TR-403	Transistor 2SC945A-C				DDBY 224003
VARIABLE	RESISTORS				
VR-501	Variable Resistor (Volume)	RV-320	50K ohm A		RRVY320001
VR-502	Variable Resistor, (Squelch)	RV-515	WITH S501 50K ohm B		
v 11-302	valiable nesistor, (Squeicn)	nv-919			RRVY515001
VR-503	Variable Resister (Clari)		WITH VR505		
	Variable Resistor (Clari)	RV-222	20K ohm B		RRVY222001
VR-504	Variable Resistor (RF Gain)	RV-353	1K ohm B		RRVY353001
			WITH S502		
VR-505	Variable Resistor (DIM)	RV-515	1K ohm B		RRVY515001
			WITH VR502		
MISCELLAN	IEOUS				r
	PC Board, Main Assy				524CPC965
	PC Board, Mod, AMP Assy				524CPC951
	PC Board, SW Assy				524CPC952
	PC Board, CH SW Assy				524CPC954
	PC Board, Mic Jack Assy				524CPC465
	PC Board, Check Point				524CPC834
TP-6	Terminal, Check Point	TP-044		x	JJPY 044001
TP-7	Terminal, Check Point	TP-044			JJPY 044001
TP-8	Terminal, Check Point	TP-044			JJPY 044001
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REF. NO.	DESCRIPTION	RS. PART NO.	MFRS PART NO.
FL-1 SP-501 M-401 J-504 J-505 J-501 J-1 J-2	Filter, CrystalFL-090SpeakerSP-057MeterMT-193MicrophoneMK-115Receptacle, DC PowerJK-052 (BL)Jack, AntennaJK-068Jack, MicrophoneJK-125Jack, SpeakerJK-089Jack, SpeakerJK-089Transformer, AF ChokeTF-083Insulation SheetYD-047, for IC-4Insulation SheetYY-027, for TR35,44Insulation SheetYY-027, for 38,39,44FuseFS-014 4(A)DC Power CordW-070234		FFLY 090001 ASPY 057001 ZMTY 193001 AMKY115001 JJKY 052001 JJKY 068001 JJKY 089001 JJKY 089001 JJKY 089001 TTFY 083001 ZYDY 047001 ZYDY 005004 ZYYY 027001 ZYYY 147001 ZFSY 014003 WZDZ 070734
FC-1 FC-2	Flat CableWF-004Flat CableWF-004		WWZY004001 WWZY004001

## **18. MECHANICAL PARTS LIST**

REF. NO.	DESCRIPT	ION		RS. PART NO.	MFRS PART NO.
1	Chassis, Side	SPCC ZMC	t=1.0		MDBP 310092A
	Chassis, Rear	ALPL	t=2.0		MDBA 310094
3	Lug Terminal, Ground	BsPL Ni	t=0.3		MZTT 150007
4	Cover, Top	SBK-08S	t=1.0		MDBP 205979A
5	Cover, Bottom	SBK-08S	t=1.0		MDBP 205980A
2 3 4 5 6 7	Mounting Bracket	SPCC ZMC	t=1.6		MDBP 406058
7	Hanger, Microphone	SPCC Ni	t=1.0		MDBP 402919
8	Heat Sink	ALPL	t=2.0		MDBP 411016
10	Ground Plate	SPT	t=0.3		MDBP 402163
10	Holder, Switch	SPCC ZMC	0-1		MDBP 411043
12	Panel, Front Knob Channel	ABS ABS	Cr-1 Cr-1		MDMP 208130A MDMP 404011
13	Knob	ABS	Cr-1 Cr-1		MDMP 404011 MDMP 404151
14	Knob	ABS	Cr-1		MDMP 404151 MDMP 403072
15	Knob	ABC	Cr-1		MDMP 401728
16	Holder, LED	EPT			MDMP 403877
17	Screw, Mounting	ABS			MDMC 405736
18	Optical Filter, Channel Display		t=1.0		MDAP 411051
19	Nameplate, Control	ALP	t=0.5		MDNP 408132A
20	Nameplate, Brand	ALP	t=0.5		MDNP 411044
21	ID Plate, FCC	ALP	t=1.0		MDNP 411045
22	Stud				MDHP 401698
23	Washer, Rubber				MDMP 409915
24	Washer, Rubber		t=2.0		MDZP 400638
25	Optical Shielding Cloth		t=0.3		MDZP 404304
27	Insulation Plate				MDZP 410274
21	Label, Production Date Label, Fuse		50μ		MDLP 402854 MDLP 408137
	Label, Warning, DC Cord		50μ		MDLP 408137 MDLP 402800
30	Screw, Pan Hd Plastic	M3 x 6			MZSS 123006
31	Screw, Flat Hd	M3 x 5	Ni		MZSN 133005
32	Screw, Bind Hd	M2.6 x 10	Ni		MZSN 192610
33	Screw, Bind Hd	M2.6 x 12	Ni		MZSN 192612
34	Screw, Bind Hd	M3 x 6	Ni		MZSN 193006
35	Screw, Bind Hd	M3 x 8	Ni	• • • • • • •	MZSN 193008
36	Screw, Bind Hd	M3 x 16	Ni		MZSN 193016
37	Screw, Bind Hd	M3 x 5	Ni		MZSB 193005
38	Tapping Screw, Bind Hd	φ3 x 6	Ni		MZSN 263006
39	Tap Tight Screw, Bind Hd	M3 x 6	ZMC		MZSZ 343006
40	Tapping Screw, Round Hd	φ3.5 x 8	ZMC		MZSZ 293508
41 42	Tapping Screw, Pan Hd	$\phi$ 5 x 16	ZMC		MZSZ 235016
42	Tapping Screw, Flat Hd Nut, Hex	φ2.5 x 6 M2.6	Ni		MZSZ 342506
43	Nut, Flange	M2.0 M3	ZMC		MZSN 430026 MZSZ 480030
45	Washer, Lock	3.5	ZMC		MZSZ 530035
46	Washer, Star	5	ZMC		MZSZ 530055 MZSZ 540050
47	Spring Plate, Knob	<i>#</i> 6600	21010		MZTT 200003
48	Spring Plate, Knob	#8500			MZTT 200002
49	Spring Plate, Knob	#7800			MZTT 200001
50	Rivet, AL, ID Plate	$\phi$ 3.2 x 5L			MZTT 213250

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